

PCTEST ENGINEERING LABORATORY, INC.

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HEARING AID COMPATIBILITY

Applicant Name:

Samsung Electronics Co., Ltd. 416 Maetan 3-Dong, Yeongtong-gu, Suwon-si Gyeonggi-do, 443-742, Republic of Korea

0Y1208

FCC ID:

A3LSGHT889

APPLICANT:

SAMSUNG ELECTRONICS CO., LTD.

Date of Testing:

Test Site/Location:

Test Report Serial No.:

241215.A3L

PCTEST Lab, Columbia, MD, USA

9/6/2012

Scope of Test: Application Type: FCC Rule Part(s): HAC Standard: EUT Type: Model(s): Tx Frequencies Tested: RF Emissions Testing Certification § 20.19(b), §6.3(v), §7.3(v) ANSI C63.19-2007; Portable Handset SGH-T889 824.20 - 848.80 MHz (GSM 850) 1850.20 - 1909.80 MHz (GSM 1900) 826.40 - 846.60 MHz (WCDMA850) 1712.4 - 1752.5 MHz (AWS WCDMA) 1852.4 - 1907.6 MHz (WCDMA1900) Pre-Production Sample [S/N: RF-6 HAC]

Test Device Serial No.:

C63.19-2007 HAC Category:

M3 (RF EMISSIONS CATEGORY)

This wireless portable device has been shown to be hearing-aid compatible under the above rated category, specified in ANSI/IEEE Std. C63.19-2007 and had been tested in a ccordance with the specified measurement procedures. Hear ing-Aid Compatibility is based on the assumption that all production units will be designed electrically identical to the device tested in this report. Test results reported herein relate only to the item(s) tested.

I attest to the accuracy of data. All measurements reported herein were performed by me or were made under my supervision and are correct to the best of my knowledge and belief. I assume full responsibility for the completeness of these measurements and vouch for the qualifications of all persons taking them.

PCTEST certifies that no party to this application has been subject to a denial of Federal benefits that includes FCC benefits pursuant to Section 5301 of the Anti-Drug Abuse Act of 1988, 21 U.S.C. 862.

Randy Ortanez President



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1. INTRODUCTION

On July 10, 2003, the Federal Communications Commission (FCC) adopted new rules requiring wireless manufacturers and service providers to provide digital wireless phones that are compatible with hearing aids. The FCC has modified the exemption for wireless phones under the Hearing Aid Compatibility Act of 1998 (HAC Act) in WT Docket 01-309 RM-8658¹ to extend the benefits of wireless telecommunications to individuals with hearing disabilities. These benefits encompass business, social and emergency communications, which increase the value of the wireless network for everyone. An estimated more than 10% of the population in the United States show signs of hearing impairment and of that fraction, almost 80% use hearing aids. Approximately 500 million people worldwide suffer from hearing loss.

Compatibility Tests Involved:

The standard calls for wireless communications devices to be measured for:

- RF Electric-field emissions
- RF Magnetic-field emissions
- T-coil mode, magnetic-signal strength in the audio band
- T-coil mode, magnetic-signal frequency response through the audio band
- T-coil mode, magnetic-signal and noise articulation index

The hearing aid must be measured for:

- RF immunity in microphone mode
- RF immunity in T-coil mode

In the following tests and results, this report includes the evaluation for a wireless communications device.



Figure 1-1 Hearing Aid in-vitu

¹ FCC Rule & Order, WT Docket 01-309 RM-8658

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2. TEST SITE LOCATION

2.1 INTRODUCTION

The map at the right shows the location of the PCTEST LABORATORY in Columbia, Maryland. It is in proximity to the FCC Laboratory, the Baltimore-Washington International (BWI) airport, the city of Baltimore and Washington, DC (See Figure 2).

These measurement tests were conducted at the PCTEST Engineering Laboratory, Inc. facility in New Concept Business Park, Guilford Industrial Park, Columbia, Maryland. The site address is 6660-B Dobbin Road, Columbia, MD 21045. The test site is one of the highest points in the Columbia area with an elevation of 390 feet above mean sea level. The site coordinates are 39° 11'15" N latitude and 76° 49' 38" W longitude. The facility is 1.5 miles North of the FCC laboratory, and the ambient signal and ambient signal strength are approximately equal to those of the FCC laboratory. There are no FM or TV

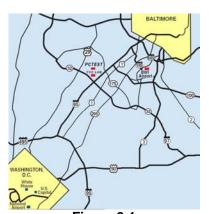


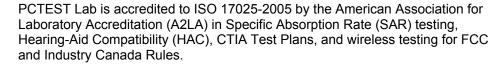
Figure 2-1 Map of the Greater Baltimore and Metropolitan Washington, D.C. area

transmitters within 15 miles of the site. The detailed description of the measurement facility was found to be in compliance with the requirements of § 2.948 according to ANSI C63.4 on January 27, 2006 and Industry Canada.

2.2 Test Facility / Accreditations:

Measurements were performed at an independent accredited PCTEST Engineering Lab located in Columbia, MD 21045, U.S.A.





- PCTEST Lab is accredited to ISO 17025 by U.S. National Institute of Standards and Technology (NIST) under the National Voluntary Laboratory Accreditation Program (NVLAP Lab code: 100431-0) in EMC, FCC and Telecommunications.
- PCTEST facility is an FCC registered (PCTEST Reg. No. 90864) test facility with the site description report on file and has met all the requirements specified in Section 2.948 of the FCC Rules and Industry Canada (IC-2451).
- PCTEST Lab is a recognized U.S. Conformity Assessment Body (CAB) in EMC and R&TTE (n.b. 0982) under the U.S.-EU Mutual Recognition Agreement (MRA).
- PCTEST TCB is a Telecommunication Certification Body (TCB) accredited to ISO/IEC Guide 65 by the American National Standards Institute (ANSI) in all scopes of FCC Rules and all Industry Canada Standards (RSS).
- PCTEST facility is an IC registered (IC-2451) test laboratory with the site description on file at Industry Canada.
- PCTEST is a CTIA Authorized Test Laboratory (CATL) for AMPS and CDMA, and EvDO mobile phones.
- PCTEST is a CTIA Authorized Test Laboratory (CATL) for Over-the-Air (OTA) Antenna Performance testing for AMPS, CDMA, GSM, GPRS, EGPRS, UMTS (W-CDMA), CDMA 1xEVDO Data, CDMA 1xRTT Data.

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EUT DESCRIPTION 3.



FCC ID: Manufacturer:	A3LSGHT889 Samsung Electronics Co., Ltd.
	416 Maetan 3-Dong, Yeongtong-gu, Suwon-si Gyeonggi-do, 443-742, Republic of Korea
Model(s): SGH-T889	
Serial Number:	RF-6 HAC
Tx Frequencies Tested:	824.20 - 848.80 MHz (GSM 850)
	1850.20 - 1909.80 MHz (GSM 1900)
	826.40 - 846.60 MHz (WCDMA850)
	1712.4 - 1752.5 MHz (AWS WCDMA)
	1852.4 - 1907.6 MHz (WCDMA1900)
Antenna Configurations:	Internal Antenna
Maximum Tested Conducted Power (HAC):	33.43 dBm (GSM 850), 30.50 dBm (GSM 1900), 23.04 dBm (WCDMA850), 22.89 dBm (AWS WCDMA), 23.09 dBm (WCDMA1900)
HAC Test Configurations:	GSM 850, 128, 190, 251, BT Off, WLAN Off, LTE Off
	GSM 1900, 512, 661, 810, BT Off, WLAN Off, LTE Off
	WCDMA850, 4132, 4183, 4233, BT Off, WLAN Off, LTE Off
	AWS WCDMA, 1312, 1412, 1862, BT Off, WLAN Off, LTE Off
	WCDMA1900, 9262, 9400, 9538, BT Off, WLAN Off, LTE Off
EUT Type:	Portable Handset

EUT	Type:
-----	-------

Air-Interface	Band (MHz)	Туре	C63.19/tested	Simultaneous Transmissions (Not to be tested)	Reduced power 20.19 (c)(1)	Voice Over Digital Transport (Data)
	850	Voice	Yes	Yes: BT or WIFI	N/A	N/A
GSM	1900	Voice	163	Tes. BT OF WITT	N/A	N/A
	GPRS/EDGE	Data	N/A	Yes: BT or WIFI	N/A	Yes
	850					
WCDMA	1700	Voice	Yes	Yes: BT or WIFI	N/A	N/A
WEDIVIA	1900					
	HSPA	Data	N/A	Yes: BT or WIFI	N/A	Yes
LTE	700	Data	N/A	Yes: BT or WIFI	N/A	Yes
LIL	1700	Data				
ВТ	2450	Data	N/A	Yes: GSM, WCDMA, or LTE	N/A	N/A
	2450	Data	N/A	Yes: GSM, WCDMA, or LTE	N/A	Yes
	5200				N/A	
WIFI	5300	Data	N/A	Yes: GSM or WCDMA		Yes
	5500				.,	
	5800					
NOTE: HAC Ra	ating was not based	on concurrent voice	e and data mode	es. Standalone mode was fou	ind to represen	t worst case rating.

Table 3: A3LSGHT889 Air Interfaces

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ANSI/IEEE C63.19 PERFORMANCE CATEGORIES 4.

I. RF EMISSIONS

The ANSI Standard presents performance requirements for acceptable interoperability of hearing aids with wireless communications devices. When these parameters are met, a hearing aid operates acceptably in close proximity to a wireless communications device.

Category	Telephone RF Parameters				
Near field Category	E-field emissions CW dB(V/m) H-field emissions CW CW dB(A/m)				
	f < 960 MHz				
M1	56 to 61 + 0.5 x AWF	5.6 to 10.6 +0.5 x AWF			
M2	51 to 56 + 0.5 x AWF	0.6 to 5.6 +0.5 x AWF			
M3	46 to 51 + 0.5 x AWF	-4.4 to 0.6 +0.5 x AWF			
M4	< 46 + 0.5 x AWF < -4.4 + 0.5 x AWF				
	f > 960 MHz				
M1	46 to 51 + 0.5 x AWF	-4.4 to 0.6 +0.5 x AWF			
M2	41 to 46 + 0.5 x AWF	-9.4 to -4.4 +0.5 x AWF			
M3	36 to 41 + 0.5 x AWF	-14.4 to -9.4 +0.5 x AWF			
M4	< 36 + 0.5 x AWF	< -14.4 + 0.5 x AWF			
Table 4-1 Hearing aid and WD near-field categories as defined in ANSI C63.19-2007 [2]					

II. ARTICULATION WEIGHTING FACTOR (AWF)

Standard	Technology	Articulation Weighing Factor (AWF)		
T1/T1P1/3GPP	UMTS (WCDMA)	0		
TIA/EIA/IS-2000	CDMA	0		
iDEN™	TDMA (22 and 11 Hz)	0		
J-STD-007	-5			
Table 4-2 Articulation Weighting Factors				

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SYSTEM SPECIFICATIONS 5.

ER3DV6 E-Field Probe Description

Construction:	One dipole parallel, two dipoles normal to probe axis
Calibration:	Built-in shielding against static charges In air from 100 MHz to 3.0 GHz (absolute accuracy ±6.0%, k=2)
Frequency:	100 MHz to > 6 GHz;
	Linearity: ± 0.2 dB (100 MHz to 3 GHz)
Directivity	± 0.2 dB in air (rotation around probe axis)
	± 0.4 dB in air (rotation normal to probe axis)
Dynamic Range	2 V/m to > 1000 V/m
, 0	(M3 or better device readings fall well below diode
	compression point)
Linearity:	± 0.2 dB
Dimensions	Overall length: 330 mm (Tip: 16 mm)
	Tip diameter: 8 mm (Body: 12 mm)
	Distance from probe tip to dipole centers: 2.5 mm



Figure 5-1 E-field Free-space Probe

H3DV6 H-Field Probe Description

Construction:	Three concentric loop sensors with 3.8 mm loop diameters Resistively loaded detector diodes for linear response Built-in shielding against static charges
Frequency:	200 MHz to 3 GHz (absolute accuracy ± 6.0%, k=2); Output linearized
Directivity:	± 0.25 dB (spherical isotropy error)
Dynamic Range:	10 mA/m to 2 A/m at 1 GHz
	(M3 or better device readings fall well below diode compression point)
Dimensions:	Overall length: 330 mm (Tip: 40 mm)
	Tip diameter: 6 mm (Body: 12 mm)
	Distance from probe tip to dipole centers: 3 mm
E-Field Interference:	< 10% at 3 GHz (for plane wave)



Figure 5-2 H-Field Free-space Probe

Probe Tip Description

HAC field measurements take place in the close near field with high gradients. Increasing the measuring distance from the source will generally decrease the measured field values (in case of the validation dipole approx. 10% per mm).

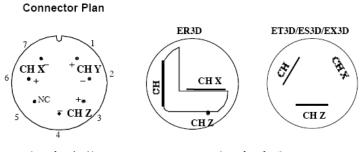
Magnetic field sensors are measuring the integral of the H-field across their sensor area surrounded by the loop. They are calibrated in a precise, homogeneous field. When measuring a gradient field, the result will be very close to the field in the center of the loop which is equivalent to the value of a homogeneous field equivalent to the center value. But it will be different from the field at the border of the loop.

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Consequently, two sensors with different loop diameters - both calibrated ideally - would give different results when measuring from the edge of the probe sensor elements. The behavior for electrically small E-field sensors is equivalent.

The magnetic field loops of the H3D probes are concentric, with the center 3mm from the tip for H3DV6. Their radius is 1.9mm.

The electric field probes have a more irregular internal geometry because it is physically not possible to have the 3 orthogonal sensors situated with the same center. The effect of the different sensor centers is accounted for in the HAC uncertainty budget ("sensor displacement"). Their geometric center is at 2.5mm from the tip, and the element ends are 1.1mm closer to the tip.



(seen from back)

(seen from front)

The antistatic shielding inside the probe is connected to the probe connector case.

Instrumentation Chain

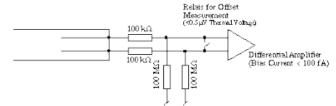
Equation 1 Conversion of Connector Voltage *u_i* to E-Field *E_i*

$$E_i = \sqrt{\frac{u_i + (u_i^2 \cdot CF)/(DCP)}{Norm_i \cdot ConvF}}$$

whereby

Ei:	electric field in V/m
Uj:	voltage of channel i at the connector in μV
Norm:	sensitivity of channel i in μV/(V/m) ²
ConvF:	enhancement factor in liquid (ConvF=1 for Air)
DCP:	diode compression point in µV
CF:	signal crest factor (peak power/average power)

Conditions of Calibration



Please note:

- · a lower input impedance of the amplifier will result in different sensitivity factors Norm, and DCP
 - larger bias currents will cause higher offset

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Probe Response to Frequency

The E-field sensors have inherently a very flat frequency response. They are calibrated with a number of frequencies resulting in a common calibration factor, with the frequency behavior documented in the calibration certificate (See also below).

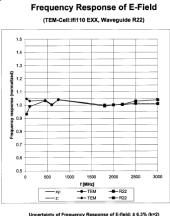
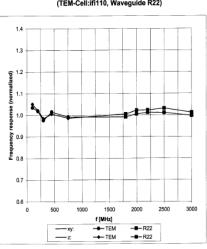


Figure 5-3 E-Field Probe Frequency Response

H-field sensors have a frequency dependent sensitivity which is evaluated for a series of frequencies also visible in the probe calibration certificate. The calibration factors result from a fitting algorithm. The proper conversion is calculated by the DASY4 software depending on the frequency setting in the procedure. See below for H-field frequency response:



Frequency Response of H-Field (TEM-Cell:ifi110, Waveguide R22)

Uncertainty of Frequency Response of E-field: ± 6.3% (k=2) Figure 5-4 H-Field Probe Frequency Response

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Conversion to Peak

Peak is defined as Peak Envelope Power. All raw measurements from the HAC measurement system are RMS values. The DASY4 system incorporates the crest factor of the signal in the computation of the RMS values (See Equation 1). Although the software also has capability to estimate the peak field by applying a square root of crest factor value to the readings, the probe modulation factor was applied manually instead per C63.19 in the measurement tables in this report. The equation to convert the raw measurements in the data tables are:

Peak Field = $20 \cdot \log (\text{Raw} \cdot \text{PMF})$

Where:

Peak Field = Peak field (in dBV/m or dBA/m) Raw = Raw field measurement from the measurement system (in V/m or A/m). PMF = Probe Modulation Factor (in linear units).

SPEAG Robotic System

E-field and H-field measurements are performed using the DASY4 automated dosimetric assessment system. The DASY4 is made by Schmid & Partner Engineering AG (SPEAG) in Zurich, Switzerland and consists of high precision robotics system (Staubli), robot controller, Pentium 4 computer, near-field probe, probe alignment sensor, and the HAC phantom. The robot is a six-axis industrial robot performing precise movements to position the probe to the location (points) of maximum electromagnetic field (EMF).



Figure 5-5 SPEAG Robotic System

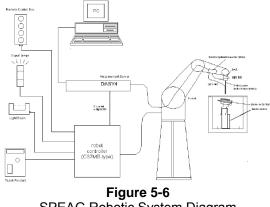
System Hardware

A cell controller system contains the power supply, robot controller, teach pendant (Joystick), and a remote control used to drive the robot motors. The PC consists of the Gateway Pentium 4 2.53 GHz computer with Windows XP system and RF Measurement Software DASY4 v4.5 (with HAC Extension), A/D interface card, monitor, mouse, and keyboard. The Staubli Robot is connected to the cell controller to allow software manipulation of the robot. A data acquisition electronic (DAE) circuit that performs the signal amplification, signal multiplexing, AD-conversion, offset measurements, mechanical surface detection, collision detection, etc. is connected to the Electro-optical coupler (EOC). The EOC performs the conversion from the optical into digital electric signal of the DAE and transfers data to the PC plug-in card.

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System Electronics

The DAE consists of a highly sensitive electrometer-grade preamplifier with auto-zeroing, a channel and gain-switching multiplexer, a fast 16 bit AD-converter and a command decoder and control logic unit. Transmission to the PC-card is accomplished through an optical downlink for data and status information and an optical uplink for commands and clock lines. The mechanical probe mounting device includes two different sensor systems for frontal and sidewise probe contacts. They are also used for mechanical surface detection and probe collision detection. The robot uses its own controller with a built in VME-bus computer.



SPEAG Robotic System Diagram

DASY4 Instrumentation Chain

The first step of the evaluation is a linearization of the filtered input signal to account for the compression characteristics of the detector diode. The compensation depends on the input signal, the diode type and the DC-transmission factor from the diode to the evaluation electronics. If the exciting field is pulsed, the crest factor of the signal must be known to correctly compensate for peak power. The formula for each channel can be given as:

$$V_i = U_i + U_i^2 \cdot \frac{cf}{dcp_i}$$

with	V_i	= compensated signal of channel i	(i = x, y, z)
	U_i	= input signal of channel i	(i = x, y, z)
	cf	= crest factor of exciting field	(DASY parameter)
	dcp_i	= diode compression point	(DASY parameter)

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From the compensated input signals the primary field data for each channel can be evaluated:

$$\begin{split} \mathrm{E-field probes}: \qquad E_i = \sqrt{\frac{V_i}{Norm_i \cdot ConvF}} \\ \mathrm{H-field probes}: \qquad H_i = \sqrt{V_i} \cdot \frac{a_{i0} + a_{i1}f + a_{i2}f^2}{f} \\ \end{split}$$
 with $V_i = \mathrm{compensated \ signal \ of \ channel \ i} \qquad (i = \mathrm{x}, \mathrm{y}, \mathrm{z}) \\ Norm_i = \mathrm{sensor \ sensitivity \ of \ channel \ i} \qquad (i = \mathrm{x}, \mathrm{y}, \mathrm{z}) \\ \mu \mathrm{V}/(\mathrm{V/m})^2 \ \mathrm{for \ E-field \ Probes} \\ ConvF = \mathrm{sensitivity \ enhancement \ in \ solution} \\ a_{ij} = \mathrm{sensor \ sensitivity \ factors \ for \ H-field \ probes} \\ f = \mathrm{carrier \ frequency \ [GHz]} \\ E_i = \mathrm{electric \ field \ strength \ of \ channel \ i \ m \ V/m} \\ H_i = \mathrm{magnetic \ field \ strength \ of \ channel \ i \ m \ A/m} \end{split}$

The RSS value of the field components gives the total field strength (Hermitian magnitude):

$$E_{tot}=\sqrt{E_x^2+E_y^2+E_z^2}$$

The primary field data are used to calculate the derived field units.

The measurement/integration time per point, as specified by the system manufacturer is >500 ms.

The signal response time is evaluated as the time required by the system to reach 90% of the expected final value after an on/off switch of the power source with an integration time of 500 ms and a probe response time of <5 ms. In the current implementation, DASY4 waits longer than 100 ms after having reached the grid point before starting a measurement, i.e., the response time uncertainty is negligible.

If the device under test does not emit a CW signal, the integration time applied to measure the electric field at a specific point may introduce additional uncertainties due to the discretization. The tolerances for the different systems had the worst-case of 2.6%.

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6. TEST PROCEDURE

I. RF EMISSIONS

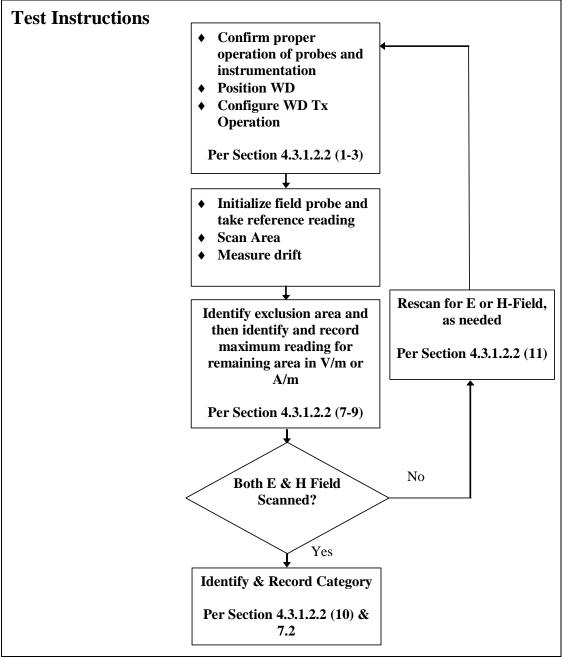
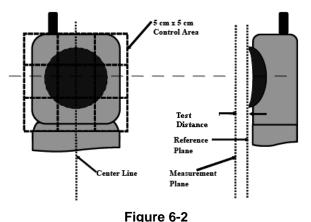
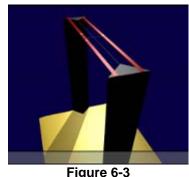


Figure 6-1 RF Emissions Flow Chart

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Test Setup





HAC Phantom

Photographs for actual WD scan grid overlay)

E/H-Field Emissions Test Setup Diagram (See Test

RF Emissions Test Procedure:

The following illustrate a typical RF emissions test scan over a wireless communications device:

- 1. Proper operation of the field probe, probe measurement system, other instrumentation, and the positioning system was confirmed.
- 2. WD is positioned in its intended test position, acoustic output point of the device perpendicular to the field probe.
- 3. The WD operation for maximum rated RF output power was configured and confirmed with the base station simulator, at the test channel and other normal operating parameters as intended for the test. The battery was ensured to be fully charged before each test.
- 4. The center sub-grid was centered over the center of the acoustic output (also audio band magnetic output, if applicable). The WD audio output was positioned tangent (as physically possible) to the measurement plane.
- 5. A surface calibration was performed before each setup change to ensure repeatable spacing and proper maintenance of the measurement plane using the HAC Phantom.
- 6. The measurement system measured the field strength at the reference location.
- 7. Measurements at 2mm or 5mm increments in the 5 x 5 cm region were performed at a distance 15 mm from the center point of the probe measurement element to the WD. A 360° rotation about the azimuth axis at the maximum interpolated position was measured. For the worst-case condition, the peak reading from this rotation was used in re-evaluating the HAC category.
- 8. The system performed a drift evaluation by measuring the field at the reference location.
- 9. Steps 1-8 were done for both the E and H-Field measurements.

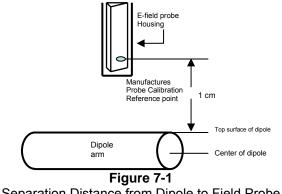
FCC ID: A3LSGHT889		HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
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7. SYSTEM CHECK

System Check Parameters I.

The input signal was an un-modulated continuous wave. The following points were taken into consideration in performing this check:

- Average Input Power P = 100mW RMS (20dBm RMS) after adjustment for return loss
- The test fixture must meet the 2 wavelength separation criterion
- The proper measurement of the 1 cm probe to dipole separation, which is measured from top surface of the dipole to the calibration reference point of the sensor, defined by the probe manufacturer is shown in the following diagram:



Separation Distance from Dipole to Field Probe

RF power was recorded using both an average reading meter and a peak reading meter. Readings of the probe are provided by the measurement system.

To assure proper operation of the near-field measurement probe the input power to the dipole shall be commensurate with the full rated output power of the wireless device (e.g. - for a cellular phone wireless device the average peak antenna input power will be on the order of 100mW (i.e. - 20dBm) RMS after adjustment for any mismatch.

II. Validation Procedure

A dipole antenna meeting the requirements given in C63.19 was placed in the position normally occupied by the WD.

The length of the dipole was scanned with both E-field and H-field probes and the maximum values for each were recorded.

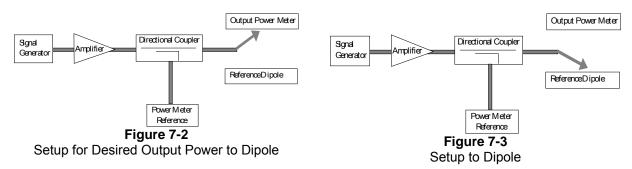
Measurement of CW

Using the near-field measurement system, scan the antenna over the radiating dipole and record the greatest field reading observed. Due to the nature of E-fields about free-space dipoles, the two E-field peaks measured over the dipole are averaged to compensate for non-parallelity of the setup (

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see manufacturer method on dipole calibration certificates, page 2). Field strength measurements shall be made only when the probe is stationary.

RF power was recorded using both an average and a peak power reading meter.

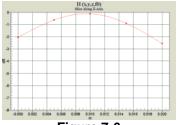


Using this setup configuration, the signal generator was adjusted for the desired output power (100mW) at a specified frequency. The reference power from the coupled port of the directional coupler is recorded. Next, the output cable is connected to the reference dipole, as shown in Figure 7-3.

The input signal level was adjusted until the reference power from the coupled port of the directional coupler was the same as previously recorded, to compensate for the impedance mismatch between the output cable and the reference dipole. To assure proper operation of the near-field measurement probe the input power to the reference dipole was verified to the full rated output power of the wireless device. The dipole was secured in a holder in a manner to meet the 20 dB reflection. The near-field measurement probe was positioned over the dipole. The antenna was scanned over the appropriate sized area to cover the dipole from end to end. SPEAG uses 2D interpolation algorithms between the measured points. Please see below two dimensional plots showing that the interpolated values interpolate smoothly between 5mm steps for a free-space RF dipole:



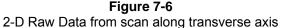
2-D Raw Data from scan along dipole axis





2-D Interpolated points from scan along dipole axis





2-D Interpolated points from scan along transverse axis

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III. System Check Results

Validation Results

Frequency (MHz)	Dipole S/N	Input Power (dBm)	E-field Result (V/m)	Target Field (V/m)	% Deviation	
835	1003	20.0	164.1	166.0	-1.1%	
1730	1137	20.0	152.3	151.5	0.5%	
1880	1137	20.0	132.9	136.8	-2.9%	
Frequency (MHz)	Dipole S/N	Input Power (dBm)	H-field Result (A/m)	Target Field (A/m)	% Deviation	
	Dipole S/N 1003	Power	Result	Field		
(MHz)		Power (dBm)	Result (A/m)	Field (A/m)	Deviation	

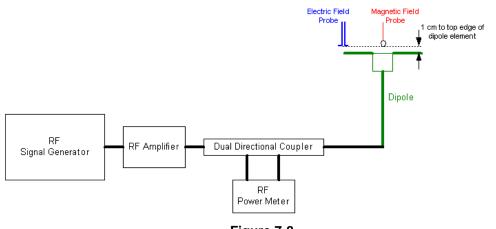


Figure 7-8 System Check Setup

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8. MODULATION FACTOR

A calibration was made of the modulation response of the probe and its instrumentation chain. This calibration was performed with the field probe, attached to its instrumentation. The response of the probe system to a CW field at the frequency of interest is compared to its response to a modulated signal with equal peak amplitude to that of a CW signal. The field level of the test signals are ensured to be more than 10 dB above the ambient level and the noise floor of the instrumentation being used. The ratio of the CW reading to that taken with a modulated reading was applied to the DUT measurements.

All voice modes for this device have been investigated in this section of the report. According to the FCC 3G Measurement Procedures, May 2006 for RF Emissions, variations in peak field and power readings.

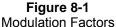
This was done using the following procedure:

- 1. The probe was illuminated with a CW signal at the intended measurement frequency and wireless device power.
- 2. The probe was positioned at the field maxima over the dipole antenna (determined after an area scan over the dipole) illuminated with the CW signal.
- 3. The reading of the probe measurement system of the CW signal at the maximum point was recorded.
- 4. Using a Spectrum Analyzer, the modulated signal adjusted with the same peak level of the CW signal was determined.
- 5. The probe measurement system reading was recorded with the modulated signal. The appropriate system crest factors for the modulation type were configured in the software to the system measurements.
- 6. The ratio of the CW reading to modulated signal reading is the probe modulation factor (PMF) for the modulation and field probe combination. This was repeated for 80% AM.
- 7. Steps 1-6 were repeated at all frequency bands and for both E and H field probes.

The modulation factors obtained were applied to readings taken of the actual wireless device, in order to obtain an accurate peak field reading using the formula:

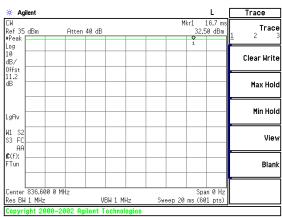
Modulation Factors:

						f (MHz)	Protocol	E-Field (V/m)	H-Field (A/m)	E-Field Modulation Factor	H-Field Modulation Factor
				E-Field	H-Field	835	AM	175.1	0.4947	1.385	1.313
f (MHz)	Protocol	E-Field (V/m)	H-Field (A/m)	Modulation	Modulation	835	WCDMA	252.3	0.703	0.961	0.924
		(1,11)	(2411)	Factor	Factor	835	CW	242.5	0.6497		
835	AM	629.3	2.212	1.290	0.910	1730	AM	136.9	0.5584	1.449	1.222
835	GSM	287	1.033	2.829	1.948	1730	WCDMA	201.1	0.7426	0.986	0.919
835	CW	811.8	2.012			1730	CW	198.3	0.6825		
1880	AM	390.8	1.215	1.319	1.115	1880	AM	129.2	0.5285	1.449	1.219
1880	GSM	184.8	0.5843	2.790	2.319	1880	WCDMA	192.5	0.6853	0.972	0.940
1880	CW	515.6	1.355			1880	CW	187.2	0.6442		

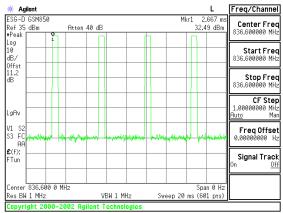


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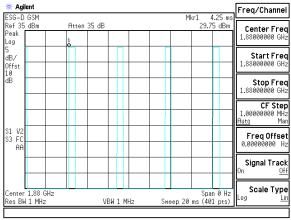














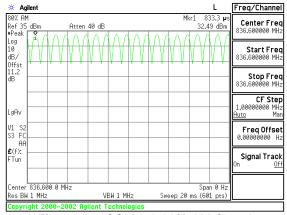


Figure 8-3 GSM850 80% AM Signal

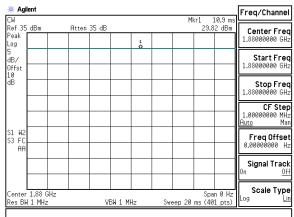


Figure 8-5 PCS CW Signal

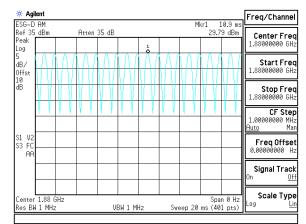


Figure 8-7 PCS 80% AM Signal

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9. FCC 3G MEASUREMENT PROCEDURES

Power measurements were performed using a base station simulator under digital average power.

I. Procedures Used to Establish RF Signal for HAC Testing

The handset was placed into a simulated call using a base station simulator in a shielded chamber. Such test signals offer a consistent means for testing HAC and are recommended for evaluating HAC. Measurements were taken with a fully charged battery. In order to verify that the device was tested and maintained at full power, this was configured with the base station simulator. The HAC measurement software calculates a reference point at the start and end of the test to check for power drifts. If conducted power deviations of more than 5% occurred, the tests were repeated.

II. HAC Measurement Conditions for WCDMA

Output Power Verification

Maximum output power is verified on the High, Middle and Low channels according to the general descriptions in section 5.2 of 3GPP TS 34.121, using the appropriate RMC or AMR with TPC (transmit power control) set to all "1s".

HAC Measurements

HAC is measured using the 12.2 kbps RMC with TPC bits configured to all "1s". HAC in AMR configurations is not required when the maximum average output of each RF channel for 12.2 kbps AMR is less than ¼ dB higher than that measured in 12.2 kbps RMC. Otherwise, HAC is measured on the maximum output channel in 12.2 AMR with a 3.4 kbps SRB (signaling radio bearer) using the configuration that results in the highest HAC for that RF channel in 12.2 RMC.

GSM RF Co	nducted Pow	ver Table
Band	Channel	GSM [dBm] CS (1 Slot)
	128	33.04
Cellular	190	33.43
	251	33.15
	512	30.50
PCS	661	29.73
	810	30.27

WCDMA RF Conducted Power Table									
3GPP 34.121 Subtest	Cellu	lar Band [dBm]	AWS Band [dBm]			PCS Band [dBm]		
Subtest	41 32	4183	4233	1312	1412	1862	9262	9400	9538
12.2 kbps RMC	22.97	23.02	23.04	22.85	22.89	22.67	23.09	22.90	23.04
12.2 kbps AMR	23.03	23.04	23.14	22.83	22.96	22.88	23.12	22.92	23.18

Table 9-1

Conducted Power Measurements for SGH-T889

FCC ID: A3LSGHT889		HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
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10. OVERALL MEASUREMENT SUMMARY

FCC ID:	A3LSGHT889
Model:	SGH-T889
S/N:	RF-6 HAC

I. E-FIELD EMISSIONS:

WCDMA1900

9538

off

Acoustic

23.04

	Table 10-1 HAC Data Summary for E-field										
Mode	Channel	Backlight	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Peak Field (V/m)	Peak Field (dBV/m)	FCC Limit (dBV/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 4.4
E-field Em	issions										
GSM850	128	off	Acoustic	33.04	37.38	105.8	40.49	48.50	-8.01	M4	none
GSM850	190	off	Acoustic	33.43	28.95	81.9	38.26	48.50	-10.24	M4	none
GSM850	251	off	Acoustic	33.15	32.21	91.1	39.19	48.50	-9.31	M4	none
GSM1900	512	off	Acoustic	30.50	22.40	62.5	35.92	38.50	-2.58	M3	none
GSM1900	661	off	Acoustic	29.73	23.84	66.5	36.46	38.50	-2.04	M3	none
GSM1900	810	off	Acoustic	30.27	22.78	63.6	36.06	38.50	-2.44	M3	none

GSM1900	810	off A	Acoustic	30.27	22.78	63.6	36.06	38.50	-2.44	M3	none
Mode	Channel	Backlight	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Peak Field (V/m)	Peak Field (dBV/m)	FCC Limit (dBV/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 4.4
E-field Emissio	ns										
WCDMA850	4132	off	Acoustic	22.97	33.01	31.7	30.0	51.0	-20.97	M4	none
WCDMA850	4183	off	Acoustic	23.02	23.64	22.7	27.1	51.0	-23.87	M4	none
WCDMA850	4233	off	Acoustic	23.04	27.45	26.4	28.4	51.0	-22.57	M4	none
AWS WCDMA	1312	off	Acoustic	22.85	25.01	24.7	27.8	41.0	-13.16	M4	none
AWS WCDMA	1412	off	Acoustic	22.89	24.77	24.4	27.8	41.0	-13.24	M4	none
AWS WCDMA	1862	off	Acoustic	22.67	31.39	31.0	29.8	41.0	-11.19	M4	none
WCDMA1900	9262	off	Acoustic	23.09	34.26	33.3	30.5	41.0	-10.55	M4	none
WCDMA1900	9400	off	Acoustic	22.90	35.37	34.4	30.7	41.0	-10.27	M4	none

30.66

29.8

29.5

41.0

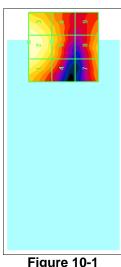


Figure 10-1 Sample E-field Scan Overlay (See Test Setup Photographs for actual WD overlay)

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M4

none

-11.51

FCC ID:	A3LSGHT889
Model:	SGH-T889
S/N:	RF-6 HAC

II. H-FIELD EMISSIONS:

Table 10-2HAC Data Summary for H-field

Mode	Channel	Backlight	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (A/m)	Peak Field (A/m)	Peak Field (dBA/m)	FCC Limit (dBA/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 4.4
H-field Emi	issions										
GSM850	128	off	Acoustic	33.04	0.0851	0.166	-15.6	-1.9	-13.71	M4	none
GSM850	190	off	Acoustic	33.43	0.0680	0.132	-17.6	-1.9	-15.66	M4	none
GSM850	251	off	Acoustic	33.15	0.0576	0.112	-19.0	-1.9	-17.10	M4	none
GSM1900	512	off	Acoustic	30.50	0.0447	0.104	-19.7	-11.9	-7.79	M4	none
GSM1900	661	off	Acoustic	29.73	0.0497	0.115	-18.8	-11.9	-6.86	M4	none
GSM1900	810	off	Acoustic	30.27	0.0547	0.127	-17.9	-11.9	-6.03	M4	none

Mode	Channel	Backlight	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (A/m)	Peak Field (V/m)	Peak Field (dBA/m)	FCC Limit (dBA/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 4.4
H-field Emissio	ns										
WCDMA850	4132	off	Acoustic	22.97	0.0714	0.066	-23.6	0.6	-24.21	M4	none
WCDMA850	4183	off	Acoustic	23.02	0.0558	0.052	-25.7	0.6	-26.35	M4	none
WCDMA850	4233	off	Acoustic	23.04	0.0616	0.057	-24.9	0.6	-25.50	M4	none
AWS WCDMA	1312	off	Acoustic	22.85	0.0533	0.049	-26.2	-9.4	-16.80	M4	none
AWS WCDMA	1412	off	Acoustic	22.89	0.0544	0.050	-26.0	-9.4	-16.63	M4	none
AWS WCDMA	1862	off	Acoustic	22.67	0.0609	0.056	-25.0	-9.4	-15.64	M4	none
WCDMA1900	9262	off	Acoustic	23.09	0.0620	0.058	-24.7	-9.4	-15.30	M4	none
WCDMA1900	9400	off	Acoustic	22.90	0.0639	0.060	-24.4	-9.4	-15.03	M4	none
WCDMA1900	9538	off	Acoustic	23.04	0.0578	0.054	-25.3	-9.4	-15.89	M4	none

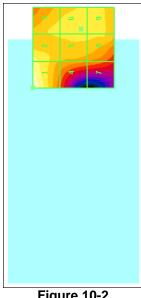


Figure 10-2 Sample H-field Scan Overlay (See Test Setup Photographs for actual WD overlay)

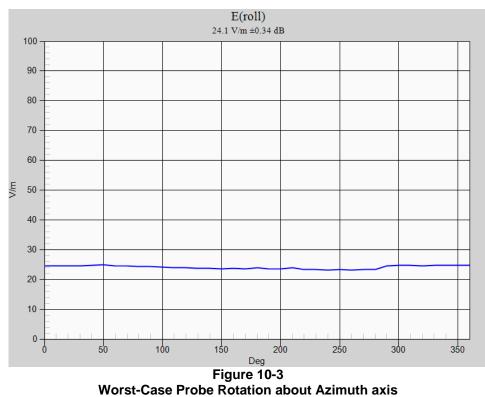
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FCC ID:	A3LSGHT889
Model:	SGH-T889
S/N:	RF-6 HAC

III. Worst-case Configuration Evaluation

	Peak Reading 360° Probe Rotation at Azimuth axis										
Mode	Channel	Backlight	Scan Center	Time Avg. Field (V/m)	Peak Field (V/m)	Peak Field (dBV/m)	FCC Limit (dBV/m)	FCC MARGIN (dB)	RESULT		
Probe Rotation at Worst-Case											
GSM1900	661	off	Acoustic	24.95	69.6	36.85	38.50	-1.65	M3		

Table 10-3



* Note: Locations of probe rotation (with and without exclusions) are shown in Figure 10-1 or Figure 10-2 denoted by the green

square markers.

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EQUIPMENT LIST 11.

Manufacturer	Model	Description	Cal Date	Cal Interval	Cal Due	Serial Number
Agilent E	4407B	ESA Spectrum Analyzer	4/3/2012	Annual	4/3/2013	US39210313
Agilent	E4432B	ESG-D Series Signal Generator	3/15/2012	Annual	3/15/2013	US40053896
Agilent	E5515C	Wireless Communications Test Set	10/10/2011	Annual	10/10/2012	GB46110872
Agilent	E5515C	Wireless Communications Test Set	10/14/2011	Annual	10/14/2012	GB41450275
Agilent	E5515C	Wireless Communications Test Set	10/20/2011	Annual	10/20/2012	GB46310798
Agilent	E5515C	Wireless Communications Test Set	2/9/2012	Annual	2/9/2013	GB43460554
Agilent	E5515C	Wireless Communications Test Set	2/12/2012	Annual	2/12/2013	GB45360985
Agilent	E5515C	Wireless Communications Test Set	2/14/2012	Annual	2/14/2013	GB43304447
Agilent	E5515C	Wireless Communications Test Set	2/14/2012	Annual	2/14/2013	GB43163447
Anritsu M	A2481A	Power Sensor	2/14/2012	Annual	2/14/2013	3681
Control Company	36934-158	Wall-Mounted Thermometer	1/4/2012	Biennial	1/4/2014	122014497
Control Company	36934-158	Wall-Mounted Thermometer	1/4/2012	Biennial	1/4/2014	122014488
Mini-Circuits	NLP-1200+	Low Pass Filter DC to 1000 MHz	N/A	CBT*	N/A	N/A
Mini-Circuits	NLP-2950+	Low Pass Filter DC to 2700 MHz	N/A	CBT*	N/A	N/A
Rohde & Schwarz	CMU200	Base Station Simulator	5/22/2012	Annual	5/22/2013	109892
Rohde & Schwarz	NRVD	Dual Channel Power Meter	4/8/2011	Biennial	4/8/2013	101695
Sækonk	NC-100	Torque Wrench (8" lb)	11/29/2011	Triennial	11/29/2014	21053
SPEAG D	AE3	Dasy Data Acquisition Electronics	11/9/2011	Annual	11/9/2012	455
SPEAG D	AE4	Dasy Data Acquisition Electronics	1/18/2012	Annual	1/18/2013	1272
SPEAG	DAE4	Dasy Data Acquisition Electronics	2/20/2012	Annual	2/20/2013	649
SPEAG	DAE4	Dasy Data Acquisition Electronics	4/19/2012	Annual	4/19/2013	665
SPEAG	DAE4	Dasy Data Acquisition Electronics	5/15/2012	Annual	5/15/2013	859
SPEAG	CD1880V3	Freespace 1880 MHz Dipole	2/9/2011	Biennial	2/9/2013	1137
SPEAG	CD835V3	Freespace 835 MHz Dipole	2/8/2011	Biennial	2/8/2013	1003
SPEAG	ER3DV6	Freespace E-field Probe	1/20/2012	Annual	1/20/2013	2353
SPEAG	H3DV6	Freespace H-field Probe	1/20/2012	Annual	1/20/2013	6207

Table 11-1

Equipment List

Calibration traceable to the National Institute of Standards and Technology (NIST).

* Note: CBT (Calibrated Before Testing). Prior to testing, the measurement paths containing a cable, attenuator, coupler or filter were connected to a calibrated source (i.e. a signal generator) to determine the losses of the measurement path. The power meter offset was then adjusted to compensate for the measurement system losses. This level offset is stored within the power meter before measurements are made. This calibration verification procedure applies to the system verification and output power measurements. The calibrated reading is then taken directly from the power meter after compensation of the losses for all final power measurements.

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12. MEASUREMENT UNCERTAINTY

Wireles	s Comm	unications De			sureme	ent		
		Uncertainty	Estimatio	n				
Uncertainty Component	Data (dB)	Data Type	Prob. Dist.	Divisor	Ci (E)	Ci (H)	Unc. (dB)	Notes/Comment s
Measurement System								
RF System Reflections	0.50	Tolerance	N	1.00	1	1	0.50	Refl. < -20 dB
Field Probe Calibration	0.21	Tolerance	N	1.00	1	1	0.21	
Field Probe Isotropy	0.01	Tolerance	Ν	1.00	1	1	0.01	
Field Probe Frequency Response	0.135	Tolerance	N	1.00	1	1	0.14	
Field Probe Linearity	0.013	Tolerance	Ν	1.00	1	1	0.01	
Probe Modulation Factor	0.270	Accuracy	R	1.73	1	1	0.16	
Boundary Effects	0.105	Accuracy	R	1.73	1	1	0.06	*
Probe Positioning Accuracy	0.20	Accuracy	R	1.73	1	0.670	0.12	*
Probe Positioner	0.050	Accuracy	R	1.73	1	0.670	0.03	*
Extrapolation/Interpolation	0.045	Tolerance	R	1.73	1	1	0.03	*
Resolution to 2mm error	0.210	Tolerance	Ν	1.00	1	1	0.21	
System Detection Limit	0.05	Tolerance	R	1.73	1	1	0.03	*
Readout Electronics	0.015	Tolerance	Ν	1.00	1	1	0.02	*
Integration Time	0.11	Tolerance	R	1.73	1	1	0.06	*
Response Time	0.033	Tolerance	R	1.73	1	1	0.02	*
Phantom Thickness	0.10	Tolerance	R	1.73	1	1	0.06	*
System Repeatability (Field x 2=power)	0.17	Tolerance	Ν	1.00	1	1	0.17	
Test Sample Related								
Device Positioning Vertical	0.2	Tolerance	R	1.73	1	1	0.12	*
Device Positioning Lateral	0.045	Tolerance	R	1.73	1	1	0.03	*
Device Holder and Phantom	0.1	Tolerance	R	1.73	1	1	0.06	*
Power Drift	0.21	Tolerance	R	1.73	1	1	0.12	
Combined Standard Uncertainty (k=1)				-			0.66	16.5%
Expanded Uncertainty [95% confidence] (k=2)						1.33	32.3%
Expanded Uncertainty [95% confidence] on Field	1					0.66	16.2%

Table 12-1

Uncertainty Estimation Table

Notes:

- Test equipments are calibrated according to techniques outlined in NIS81, NIS3003 and NIST Tech Note 1297. All
 equipments have traceability according to NIST. Measurement Uncertainties are defined in further detail in NIS 81
 and NIST Tech Note 1297 and UKAS M3003.
- 2. * Uncertainty specifications from Schmidt & Partner Engineering AG (not site specific)

Measurement uncertainty reflects the quality and accuracy of a measured result as compared to the true value. Such statements are generally required when stating results of measurements so that it is clear to the intended audience that the results may differ when reproduced by different facilities. Measurement results vary due to the measurement uncertainty of the instrumentation, measurement technique, and test engineer. Most uncertainties are calculated using the tolerances of the instrumentation used in the measurement, the measurement setup variability, and the technique used in performing the test. While not generally included, the variability of the equipment under test also figures into the overall measurements (so-called Type A uncertainty). This may mean that the Hearing Aid immunity tests may have to be repeated by taking down the test setup and resetting it up so that there are a statistically significant number of repeat measurements to identify the measurement uncertainty. By combining the repeat measurements to identify the measurement uncertainty. By combining the repeat measurements to identify the measurement uncertainty. By and NIS 3003, the overall measurement uncertainty was estimated.

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TEST DATA 13.

See following Attached Pages for Test Data.

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DUT: CD835V3 - SN1003

Type: CD835V3 Serial: 1003

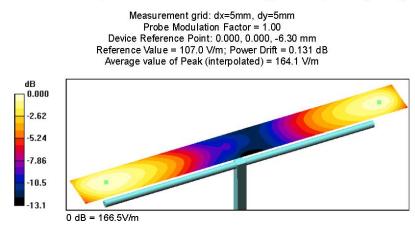
Communication System: CW; Frequency: 835 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

DASY5 Configuration:

- Probe: ER3DV6 SN2353; Calibrated: 1/20/2012
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- · Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

835 MHz / 100mW HAC Dipole Validation at 10mm/Hearing Aid Compatibility Test (41x361x1):



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DUT: CD835V3 - SN1003

Type: CD835V3 Serial: 1003

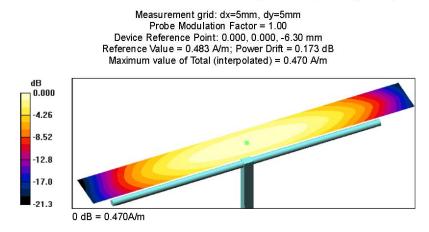
Communication System: CW; Frequency: 835 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

DASY5 Configuration:

- Probe: H3DV6 SN6207; Calibrated: 1/20/2012
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- · Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

835 MHz / 100 mW HAC Validation at 10 mm/Hearing Aid Compatibility Test (41x361x1):



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DUT: CD1880V3 - SN1137

Type: CD1880V3 Serial: 1137

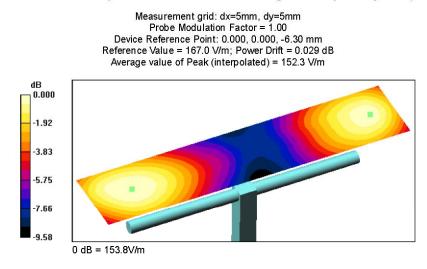
Communication System: CW; Frequency: 1730 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

DASY5 Configuration:

- Probe: ER3DV6 SN2353; Calibrated: 1/20/2012
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- · Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

1730 MHz / 100mW HAC Dipole Validation at 10mm/Hearing Aid Compatibility Test (41x181x1):



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DUT: CD1880V3 - SN1137

Type: CD1880V3 Serial: 1137

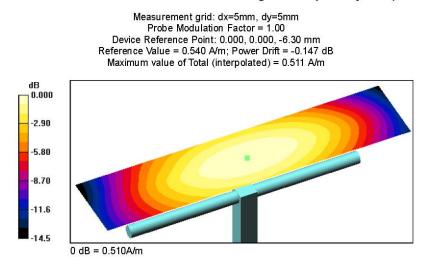
Communication System: CW; Frequency: 1730 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

DASY5 Configuration:

- Probe: H3DV6 SN6207; Calibrated: 1/20/2012
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- · Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

1730 MHz / 100 mW HAC Validation at 10 mm/Hearing Aid Compatibility Test (41x181x1):



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DUT: CD1880V3 - SN1137

Type: CD1880V3 Serial: 1137

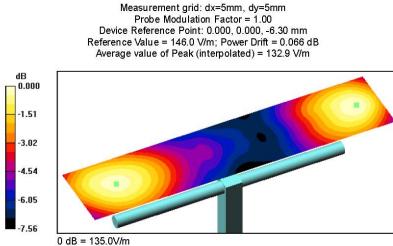
Communication System: CW; Frequency: 1880 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

DASY5 Configuration:

- Probe: ER3DV6 SN2353; Calibrated: 1/20/2012
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- · Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

1880 MHz / 100mW HAC Dipole Validation at 10mm/Hearing Aid Compatibility Test (41x181x1):



Jub - 155.0V/I

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DUT: CD1880V3 - SN1137

Type: CD1880V3 Serial: 1137

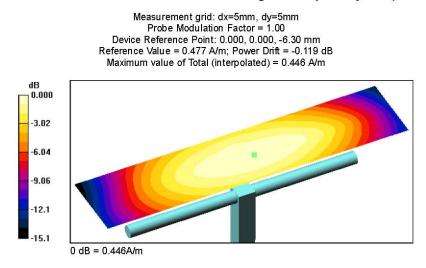
Communication System: CW; Frequency: 1880 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

DASY5 Configuration:

- Probe: H3DV6 SN6207; Calibrated: 1/20/2012
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- · Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

1880 MHz / 100 mW HAC Validation at 10 mm/Hearing Aid Compatibility Test (41x181x1):



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DUT: A3LSGHT889

Type: Portable Handset Serial: RF-6 HAC Backlight off Duty Cycle: 1:8.3

Communication System: GSM; Frequency: 824.2 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

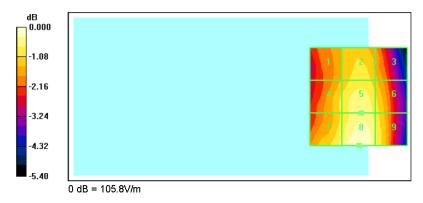
DASY5 Configuration:

- Probe: ER3DV6 SN2353; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

GSM850 Low Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 105.8 V/m Probe Modulation Factor = 2.829 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 45.4 V/m; Power Drift = 0.060 dB Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak E-field in V/m				
Grid 1	Grid 2	Grid 3		
90.4 M4	95.8 M4	91.2 M4		
Grid 4	Grid 5	Grid 6		
94.8 M4	100.6 M4	96.0 M4		
Grid 7	Grid 8	Grid 9		
99.8 M4	105.8 M4	98.9 M4		



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DUT: A3LSGHT889

Type: Portable Handset Serial: RF-6 HAC Backlight off Duty Cycle: 1:8.3

Communication System: GSM; Frequency: 824.2 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

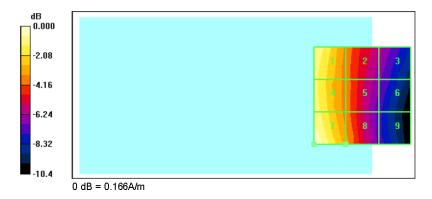
DASY5 Configuration:

- Probe: H3DV6 SN6207; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

GSM850 Low Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.166 A/m Probe Modulation Factor = 1.948 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.049 A/m; Power Drift = -0.101 dB Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in A/m					
		Grid 3			
0.157 M4	0.109 M4	0.084 M4			
		Grid 6			
0.150 M4	0.108 M4	0.077 M4			
Grid 7	Grid 8	Grid 9			
0.166 M4	0.116 M4	0.074 M4			



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DUT: A3LSGHT889

Type: Portable Handset Serial: RF-6 HAC Backlight off Duty Cycle: 1:8.3

Communication System: GSM; Frequency: 1880 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

DASY5 Configuration:

- Probe: ER3DV6 SN2353; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

GSM1900 Mid Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 66.5 V/m Probe Modulation Factor = 2.790 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 10.6 V/m; Power Drift = 0.178 dB Hearing Aid Near-Field Category: M3 (AWF -5 dB)

 Peak E-field in V/m

 Grid 1
 Grid 2
 Grid 3

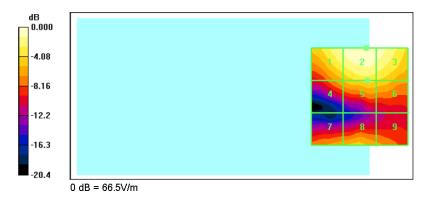
 60.6 M3
 66.5 M3
 63.7 M3

 Grid 4
 Grid 5
 Grid 6

 35.5 M4
 44.1 M4
 42.1 M4

 Grid 7
 Grid 8
 Grid 9

 34.2 M4
 38.2 M4
 32.6 M4



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DUT: A3LSGHT889

Type: Portable Handset Serial: RF-6 HAC Backlight off Duty Cycle: 1:8.3

Communication System: GSM; Frequency: 1909.8 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

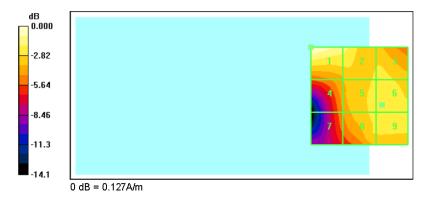
DASY5 Configuration:

- Probe: H3DV6 SN6207; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

GSM1900 High Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.127 A/m Probe Modulation Factor = 2.319 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.049 A/m; Power Drift = 0.128 dB Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in A/m								
		Grid 3						
0.127 M4	0.108 M4	0.098 M4						
Grid 4	Grid 5	Grid 6						
0.082 M4	0.100 M4	0.103 M4						
Grid 7	Grid 8	Grid 9						
0.074 M4	0.099 M4	0.102 M4						



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DUT: A3LSGHT889

Type: Portable Handset Serial: RF-6 HAC Backlight off Duty Cycle: 1:1

Communication System: WCDMA; Frequency: 826.4 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

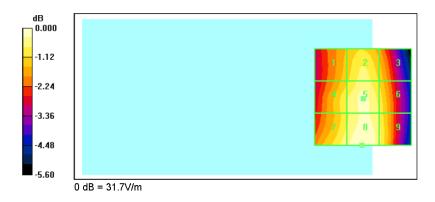
DASY5 Configuration:

- Probe: ER3DV6 SN2353; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

WCDMA850 Low Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 31.7 V/m Probe Modulation Factor = 0.961 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 40.0 V/m; Power Drift = 0.066 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

> Peak E-field in V/m Grid 1 Grid 2 Grid 3 27.7 M4 29.8 M4 27.7 M4 Grid 5 Grid 6 Grid 4 29.0 M4 30.9 M4 28.9 M4 Grid 7 Grid 8 Grid 9 30.1 M4 31.7 M4 29.5 M4



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DUT: A3LSGHT889

Type: Portable Handset Serial: RF-6 HAC Backlight off Duty Cycle: 1:1

Communication System: WCDMA; Frequency: 826.4 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

DASY5 Configuration:

- Probe: H3DV6 SN6207; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

WCDMA850 Low Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.066 A/m Probe Modulation Factor = 0.924 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.040 A/m; Power Drift = 0.156 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

 Peak H-field in A/m

 Grid 1
 Grid 2
 Grid 3

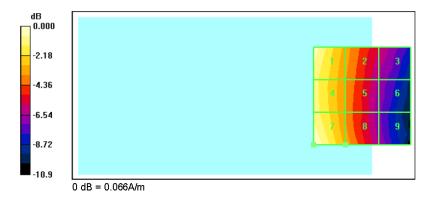
 0.064 M4
 0.046 M4
 0.034 M4

 Grid 4
 Grid 5
 Grid 6

 0.060 M4
 0.044 M4
 0.031 M4

 Grid 7
 Grid 8
 Grid 9

 0.066 M4
 0.046 M4
 0.032 M4



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DUT: A3LSGHT889

Type: Portable Handset Serial: RF-6 HAC Backlight off Duty Cycle: 1:1

Communication System: WCDMA; Frequency: 1752.5 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

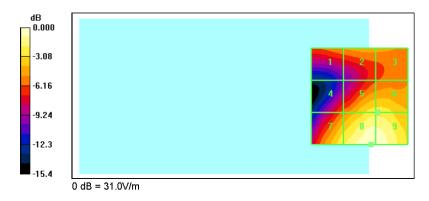
DASY5 Configuration:

- Probe: ER3DV6 SN2353; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
 Measurement SW: DASY52, V52.8 Build 1;

WCDMA1700 High Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 31.0 V/m Probe Modulation Factor = 0.986 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 18.8 V/m; Power Drift = 0.136 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

> Peak E-field in V/m Grid 1 Grid 2 Grid 3 17.3 M4 18.4 M4 18.2 M4 Grid 5 Grid 6 Grid 4 16.2 M4 23.4 M4 23.4 M4 Grid 7 Grid 8 Grid 9 24.3 M4 31.0 M4 30.4 M4



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DUT: A3LSGHT889

Type: Portable Handset Serial: RF-6 HAC Backlight off Duty Cycle: 1:1

Communication System: WCDMA; Frequency: 1752.5 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

DASY5 Configuration:

- Probe: H3DV6 SN6207; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

WCDMA1700 High Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.056 A/m Probe Modulation Factor = 0.919 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.068 A/m; Power Drift = -0.058 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

 Peak H-field in A/m

 Grid 1
 Grid 2
 Grid 3

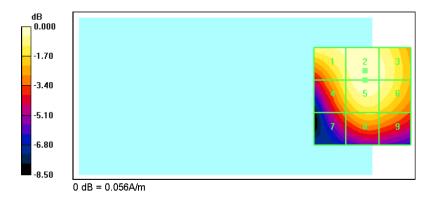
 0.053 M4
 0.056 M4
 0.054 M4

 Grid 4
 Grid 5
 Grid 6

 0.050 M4
 0.055 M4
 0.054 M4

 Grid 7
 Grid 8
 Grid 9

 0.040 M4
 0.047 M4
 0.046 M4



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DUT: A3LSGHT889

Type: Portable Handset Serial: RF-6 HAC Backlight off Duty Cycle: 1:1

Communication System: WCDMA; Frequency: 1880 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

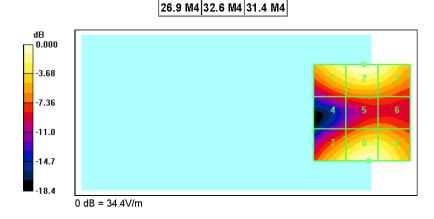
DASY5 Configuration:

- Probe: ER3DV6 SN2353; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
 Measurement SW: DASY52, V52.8 Build 1;

WCDMA1900 Mid Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 34.4 V/m Probe Modulation Factor = 0.972 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 14.1 V/m; Power Drift = -0.015 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

> Peak E-field in V/m Grid 1 Grid 2 Grid 3 31.0 M4 34.4 M4 32.1 M4 Grid 5 Grid 6 Grid 4 14.1 M4 17.4 M4 17.4 M4 Grid 7 Grid 8 Grid 9



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DUT: A3LSGHT889

Type: Portable Handset Serial: RF-6 HAC Backlight off Duty Cycle: 1:1

Communication System: WCDMA; Frequency: 1880 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

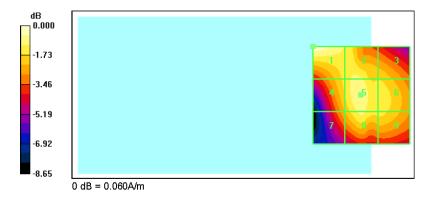
DASY5 Configuration:

- Probe: H3DV6 SN6207; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

WCDMA1900 Mid Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.060 A/m Probe Modulation Factor = 0.940 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.073 A/m; Power Drift = -0.131 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

> Peak H-field in A/m Grid 1 Grid 2 Grid 3 0.060 M4|0.053 M4|0.049 M4 Grid 4 Grid 5 Grid 6 0.050 M4 0.056 M4 0.052 M4 Grid 7 Grid 8 Grid 9 0.046 M4 0.054 M4 0.050 M4



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14. CALIBRATION CERTIFICATES

The following pages include the probe calibration used to evaluate HAC for the DUT.

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Accredited by the Swiss Accreditation Service (SAS) The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates Accreditation No.: SCS 108

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Object	ER3DV6 - SN:235	33	
Calibration procedure(s)	QA CAL-02.v6, Q/ Calibration procec evaluations in air	A CAL-25.v4 lure for E-field probes optimized f	or close near field
Calibration date:	January 20, 2012		
The measurements and the unc All calibrations have been condu	ertainties with confidence pro ucted in the closed laboratory	nal standards, which realize the physical units bability are given on the following pages and facility: environment temperature (22 ± 3)°C a	are part of the certificate.
osimisiou ∈dribueur aseo (wo	k E critical for calibration)		
	ID	Cal Date (Certificate No.)	Scheduled Calibration
Primary Standards		Cal Date (Certificate No.) 31-Mar-11 (No. 217-01372)	Scheduled Calibration Apr-12
Primary Standards Power meter E4419B	ID	·····	
Primary Standards Power meter E4419B Power sensor E4412A	ID GB41293874	31-Mar-11 (No. 217-01372)	Apr-12
Primary Standards Power meter E4419B Power sensor E4412A Reference 3 dB Attenuator	ID GB41293874 MY41498087	31-Mar-11 (No. 217-01372) 31-Mar-11 (No. 217-01372)	Apr-12 Apr-12
Primary Standards Power meter E4419B Power sensor E4412A Reference 3 dB Attenuator Reference 30 dB Attenuator	ID GB41293874 MY41498087 SN: S5054 (3c)	31-Mar-11 (No. 217-01372) 31-Mar-11 (No. 217-01372) 29-Mar-11 (No. 217-01369)	Apr-12 Apr-12 Apr-12 Apr-12
Primary Standards Power meler E4419B Power sensor E4412A Reference 3 dB Attenuator Reference 20 dB Attenuator Reference 30 dB Attenuator	ID GB41293874 MY41498087 SN: S5054 (3c) SN: S5086 (20b)	31-Mar-11 (No. 217-01372) 31-Mar-11 (No. 217-01372) 29-Mar-11 (No. 217-01369) 29-Mar-11 (No. 217-01367)	Apr-12 Apr-12 Apr-12 Apr-12 Apr-12
Primary Standards Power meter E4419B Power sensor E4412A Reference 3 dB Attenuator Reference 20 dB Attenuator Reference 30 dB Attenuator Reference Probe ER3DV6	ID GB41293874 MY41498087 SN: S5054 (3c) SN: S5086 (20b) SN: S5129 (30b)	31-Mar-11 (No. 217-01372) 31-Mar-11 (No. 217-01372) 29-Mar-11 (No. 217-01369) 29-Mar-11 (No. 217-01367) 29-Mar-11 (No. 217-01370)	Apr-12 Apr-12 Apr-12 Apr-12 Apr-12 Apr-12
Primary Standards Power meter E4419B Power sensor E4412A Reference 3 dB Attenuator Reference 20 dB Attenuator	ID GB41293874 MY41496087 SN: 55054 (3c) SN: 55086 (20b) SN: 55129 (30b) SN: 2328	31-Mar-11 (No. 217-01372) 31-Mar-11 (No. 217-01372) 29-Mar-11 (No. 217-01369) 29-Mar-11 (No. 217-01367) 29-Mar-11 (No. 217-01370) 11-Oct-11 (No. ER3-2328_Oct11)	Apr-12 Apr-12 Apr-12 Apr-12 Apr-12 Oct-12
Primary Standards Power meter E4419B Power sensor E4412A Reference 3 dB Attenuator Reference 30 dB Attenuator Reference Probe ER3DV6 DAE4	ID GB41293874 MY41498087 SN: S5054 (3c) SN: S5086 (20b) SN: S5129 (30b) SN: 2328 SN: 789	31-Mar-11 (No. 217-01372) 31-Mar-11 (No. 217-01372) 29-Mar-11 (No. 217-01369) 29-Mar-11 (No. 217-01367) 29-Mar-11 (No. 217-01370) 11-Oct-11 (No. ER3-2328_Oct11) 6-Apr-11 (No. DAE4-789_Apr11)	Apr-12 Apr-12 Apr-12 Apr-12 Oct-12 Apr-12
Primary Standards Power meter E4419B Power sensor E4412A Reference 3 dB Attenuator Reference 20 dB Attenuator Reference 30 dB Attenuator Reference Probe ER3DV6 DAE4 Secondary Standards	ID GB41293874 MY41498087 SN: S5054 (3c) SN: S5086 (20b) SN: S5129 (30b) SN: 2328 SN: 789 ID	31-Mar-11 (No. 217-01372) 31-Mar-11 (No. 217-01372) 29-Mar-11 (No. 217-01369) 29-Mar-11 (No. 217-01367) 29-Mar-11 (No. 217-01370) 11-Oct-11 (No. ER3-2328_Oct11) 6-Apr-11 (No. DAE4-789_Apr11) Check Date (in house)	Apr-12 Apr-12 Apr-12 Apr-12 Oct-12 Apr-12 Scheduled Check
Primary Standards Power meter E4419B Power sensor E4412A Reference 3 dB Attenuator Reference 30 dB Attenuator Reference 20 dB Attenuator Reference Probe ER3DV6 DAE4 Secondary Standards RF generator HP 8648C	ID GB41293874 MY41498087 SN: S5054 (3c) SN: S5086 (20b) SN: S5129 (30b) SN: 2328 SN: 789 ID US3642U01700	31-Mar-11 (No. 217-01372) 31-Mar-11 (No. 217-01372) 29-Mar-11 (No. 217-01369) 29-Mar-11 (No. 217-01367) 29-Mar-11 (No. 217-01370) 11-Oct-11 (No. ER3-2328_Oct11) 6-Apr-11 (No. DAE4-769_Apr11) Check Date (in house) 4-Aug-99 (in house check Apr-11)	Apr-12 Apr-12 Apr-12 Apr-12 Oct-12 Apr-12 Scheduled Check In house check: Apr-13
Power meter E44198 Power sensor E4412A Reference 3 dB Attenuator Reference 20 dB Attenuator Reference 30 dB Attenuator Reference Probe ER3DV6 DAE4 Secondary Standards RF generator HP 8648C	ID GB41293874 MY41498087 SN: 55054 (3c) SN: 55086 (20b) SN: 55129 (30b) SN: 2328 SN: 789 ID US3642U01700 US37390585	31-Mar-11 (No. 217-01372) 31-Mar-11 (No. 217-01372) 29-Mar-11 (No. 217-01369) 29-Mar-11 (No. 217-01367) 29-Mar-11 (No. 217-01370) 11-Oct-11 (No. ER3-2328_Oct11) 6-Apr-11 (No. DAE4-789_Apr11) Check Date (in house) 4-Aug-99 (in house check Apr-11) 18-Oct-01 (in house check Oct-11)	Apr-12 Apr-12 Apr-12 Apr-12 Oct-12 Apr-12 Oct-12 Apr-12 Scheduled Check In house check: Apr-13 In house check: Oct-12

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Accreditation No.: SCS 108

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The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Glossary:

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Olossaly.	
NORMx,y,z	sensitivity in free space
DCP	diode compression point
CF	crest factor (1/duty_cycle) of the RF signal
A, B, C	modulation dependent linearization parameters
Polarization φ	φ rotation around probe axis
Polarization 9	θ rotation around an axis that is in the plane normal to probe axis (at measurement center),
	i.e., $\vartheta = 0$ is normal to probe axis
Connector Angle	information used in DASY system to align probe sensor X to the robot coordinate system

Calibration is Performed According to the Following Standards:

 a) IEEE Std 1309-2005, "IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005.

Methods Applied and Interpretation of Parameters:

- NORMx,y,z: Assessed for E-field polarization 9 = 0 for XY sensors and 9 = 90 for Z sensor (f ≤ 900 MHz in TEM-cell; f > 1800 MHz; R22 waveguide).
 - NORM(f)x,y,z = NORMx,y,z * frequency_response (see Frequency Response Chart).
- DCPx,y,z: DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- PAR: PAR is the Peak to Average Ratio that is not calibrated but determined based on the signal characteristics
- Ax,y,z; Bx,y,z; Cx,y,z, VRx,y,z: A, B, C are numerical linearization parameters assessed based on the data of
 power sweep for specific modulation signal. The parameters do not depend on frequency nor media. VR is the
 maximum calibration range expressed in RMS voltage across the diode.
- Spherical isotropy (3D deviation from isotropy): in a locally homogeneous field realized using an open waveguide setup.
- Sensor Offset: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- Connector Angle: The angle is assessed using the information gained by determining the NORMx (no
 uncertainty required).

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ER3DV6 - SN:2353

January 20, 2012

Probe ER3DV6

SN:2353

Manufactured: March 8, 2005 January 20, 2012 Calibrated:

Calibrated for DASY/EASY Systems (Note: non-compatible with DASY2 system!)

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				04/05/10

DASY/EASY - Parameters of Probe: ER3DV6 - SN:2353

Basic Calibration Parameters

	Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm $(\mu V/(V/m)^2)$	1.53	1.73	1.81	± 10.1 %
DCP (mV) ⁸	100.9	98.7	102.3	

Modulation Calibration Parameters

UID	Communication System Name	PAR		A dB	B dB	C dB	VR mV	Unc ^E (k=2)
10000	CW	0.00	X	0.00	0.00	1.00	103.6	±3.0 %
			Y	0.00	0.00	1.00	88.2	
			Z	0.00	0.00	1.00	105.7	
10011	UMTS-FDD (WCDMA)	3.40	X	3.44	65.6	18.3	111.4	±0.7 %
			Y	3.51	65.9	18.5	130.9	
			Z	3.53	66.6	18.9	114.5	
10021	GSM-FDD (TDMA, GMSK)	9.40	X	16.75	99.3	28.2	144.6	±1.7 %
			Y	16.85	99.3	28.8	124.1	
			Z	22.94	99.8	28.7	128.7	
10039	CDMA2000 (1xRTT, RC1)	4.57	X	4.56	66.0	18.8	112.4	±0.9 %
			Y	4.84	67.1	19.5	133.1	
			Z	4.49	65.9	18.7	115.8	
10081	CDMA2000 (1xRTT, RC3)	3.96	X	3.68	64.9	18.0	109.1	±0.7 %
			Y	3.89	65.9	18.7	129.0	
			Z	3.71	65.4	18.4	113.2	
10169	LTE-FDD (SC-FDMA, 1 RB, 20 MHz, QPSK)	5.73	X	5.16	67.7	20.5	145.7	±1.7 %
			Y	5.14	67.1	20.3	124.7	
			Z	4.82	65.7	19.3	108.5	
10170	LTE-FDD (SC-FDMA, 1 RB, 20 MHz, 16-QAM)	6.52	X	6.10	69.5	21.9	146.2	±2.7 %
			Y	6.13	69.1	21.8	125.5	
			Z	5.66	67.0	20.2	110.4	
10175	LTE-FDD (SC-FDMA, 1 RB, 10 MHz, QPSK)	5.73	X	5.13	67.6	20.5	145.7	±1.7 %
			Y	5.15	67.1	20.3	124.9	
			Z	4.88	66.0	19.4	110.1	
10176	LTE-FDD (SC-FDMA, 1 RB, 10 MHz, 16-QAM)	6.52	X	6.12	69.6	22.0	145.7	±3.0 %
			Y	6.12	69.2	21.9	124.6	
			Z	5.69	67.2	20.4	110.6	
10177	LTE-FDD (SC-FDMA, 1 RB, 5 MHz, QPSK)	5.73	X	5.19	67.8	20.6	145.8	±1.7 %
			Y	5.17	67.3	20.4	124.7	
			Z	4.88	66.0	19.4	110.3	
10178	LTE-FDD (SC-FDMA, 1 RB, 5 MHz, 16- QAM)	6.52	X	6.05	69.3	21.8	146.8	±2.5 %
			Y	5.98	68.5	21.5	123.9	
			Z	5.55	66.6	20.1	109.9	
10181	LTE-FDD (SC-FDMA, 1 RB, 15 MHz, QPSK)	5.73	X	5.17	67.8	20.6	145.9	±1.7 %
			Y	4.92	66.1	19.7	123.5	
			Z	4.90	66.1	19.5	110.0	

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ER3DV6-- SN:2353

January 20, 2012

10182	LTE-FDD (SC-FDMA, 1 RB, 15 MHz, 16-QAM)	6.52	X	6.00	69.1	21.7	146.3	±3.0 %
			Y	6.43	70.5	22.6	125.7	
			Z	5.70	67.2	20.4	110.4	

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

^B Numerical linearization parameter: uncertainty not required.
^E Uncertainty is determined using the max, deviation from linear response applying rectangular distribution and is expressed for the square of the field value.

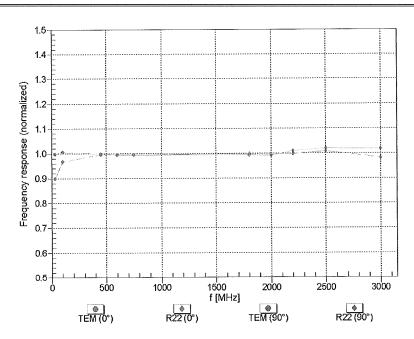
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ER3DV6- SN:2353

January 20, 2012



Frequency Response of E-Field (TEM-Cell:ifi110 EXX, Waveguide: R22)

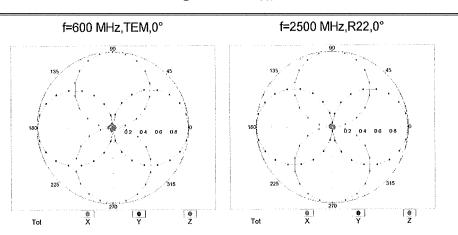
Uncertainty of Frequency Response of E-field: ± 6.3% (k=2)

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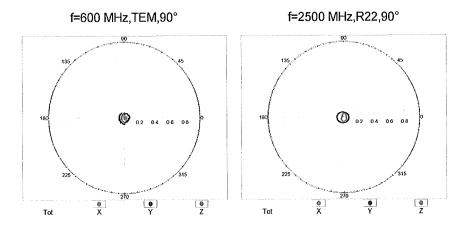
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January 20, 2012



Receiving Pattern (ϕ), $\vartheta = 0^{\circ}$

Receiving Pattern (ϕ), ϑ = 90°

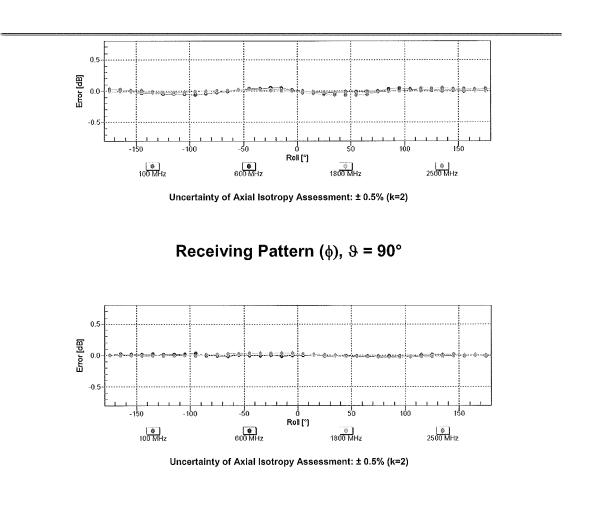


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Receiving Pattern (ϕ), $\vartheta = 0^{\circ}$

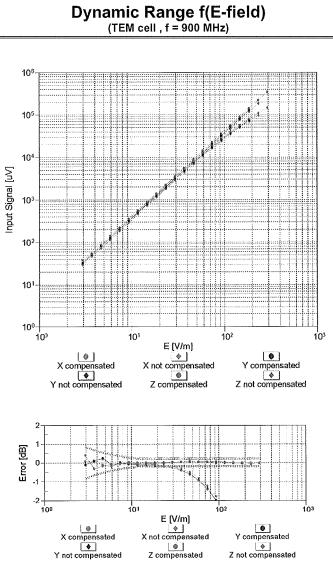
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ER3DV6-- SN:2353

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Uncertainty of Linearity Assessment: ± 0.6% (k=2)

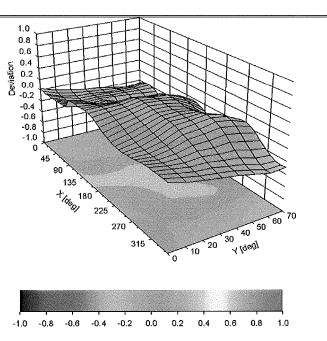
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ER3DV6- SN:2353

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Deviation from Isotropy in Air Error (ϕ , ϑ), f = 900 MHz

Uncertainty of Spherical Isotropy Assessment: ± 2.6% (k=2)

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DASY/EASY - Parameters of Probe: ER3DV6 - SN:2353

Other Probe Parameters	
Sensor Arrangement	Rectangular
Connector Angle (°)	-4.9
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	337 mm
Probe Body Diameter	10 mm
Tip Length	10 mm
Tip Diameter	8 mm
Probe Tip to Sensor X Calibration Point	2.5 mm
Probe Tip to Sensor Y Calibration Point	2.5 mm
Probe Tip to Sensor Z Calibration Point	2.5 mm

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	CERTIFICATE		
Object	H3DV6 - SN:6207		
Calibration procedure(s)	QA CAL-03.v6, QA Calibration proceed evaluations in air	A CAL-25.v4 lure for H-field probes optimized fo	
Calibration date:	January 20, 2012		1/10t
	ucted in the closed laboratory	obability are given on the following pages and a facility: environment temperature (22 \pm 3)°C a	
Primary Standards	ID	Cal Date (Certificate No.)	Scheduled Calibration
Power meter E4419B	GB41293874	31-Mar-11 (No. 217-01372)	Apr-12
Power sensor E4412A	MY41498087	31-Mar-11 (No. 217-01372)	Apr-12
Reference 3 dB Attenuator	SN: S5054 (3c)	29-Mar-11 (No. 217-01369)	Apr-12
Reference 20 dB Attenuator	SN: S5086 (20b)	29-Mar-11 (No. 217-01367)	Apr-12
Reference 30 dB Attenuator	SN: S5129 (30b)	29-Mar-11 (No. 217-01370)	Apr-12
Reference Probe H3DV6	SN: 6182	11-Oct-11 (No. H3-6182_Oct11)	Oct-12
DAE4	SN: 789	6-Apr-11 (No. DAE4-789_Apr11)	Apr-12
	ID	Check Date (in house)	Scheduled Check
Secondary Standards			In house check: Apr-13
Secondary Standards RF generator HP 8648C	US3642U01700	4-Aug-99 (in house check Apr-11)	In nouse check. Api-10
RF generator HP 8648C	US3642U01700 US37390585	4-Aug-99 (in house check Apr-11) 18-Oct-01 (in house check Oct-11)	In house check: Oct-12
RF generator HP 8648C Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-11)	In house check: Oct-12
RF generator HP 8648C	US37390585	18-Oct-01 (in house check Oct-11) Function	In house check: Oct-12 Signature

Certificate No: H3-6207_Jan12

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Glossary:

NORMx,y,z	sensitivity in free space
DCP	diode compression point
CF	crest factor (1/duty_cycle) of the RF signal
A, B, C	modulation dependent linearization parameters
Polarization φ	φ rotation around probe axis
Polarization 9	9 rotation around an axis that is in the plane normal to probe axis (at measurement center),
	i.e., 9 = 0 is normal to probe axis
Connector Angle	information used in DASY system to align probe sensor X to the robot coordinate system

Calibration is Performed According to the Following Standards:

 a) IEEE Std 1309-2005, "IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005.

Methods Applied and Interpretation of Parameters:

- NORMx, y,z: Assessed for E-field polarization θ = 0 for XY sensors and θ = 90 for Z sensor (f ≤ 900 MHz in TEM-cell; f > 1800 MHz: R22 waveguide).
- X, Y,Z(f)_a0a1a2= X, Y,Z_a0a1a2* frequency_response (see Frequency Response Chart).
- DCPx,y,z: DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- PAR: PAR is the Peak to Average Ratio that is not calibrated but determined based on the signal characteristics
- Ax,y,z; Bx,y,z; Cx,y,z, VRx,y,z: A, B, C are numerical linearization parameters assessed based on the data of
 power sweep for specific modulation signal. The parameters do not depend on frequency nor media. VR is the
 maximum calibration range expressed in RMS voltage across the diode.
- Spherical isotropy (3D deviation from isotropy): in a locally homogeneous field realized using an open waveguide setup.
- Sensor Offset: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- Connector Angle: The angle is assessed using the information gained by determining the X_a0a1a2 (no
 uncertainty required).

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January 20, 2012

H3DV6 - SN:6207

Probe H3DV6

SN:6207

Manufactured: June 12, 2006 Calibrated: January 20, 2012

Calibrated for DASY/EASY Systems (Note: non-compatible with DASY2 system!)

Certificate No: H3-6207_Jan12

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January 20, 2012

DASY/EASY - Parameters of Probe: H3DV6 - SN:6207

		Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm (A/m / √(mV))	a0	2.41E-003	2.37E-003	2.94E-003	± 5.1 %
Norm (A/m / √(mV))	a1	1.77E-004	6.07E-004	8.69E-005	± 5.1 %
Norm (A/m / $\sqrt{(mV)}$)	a2	1.63E-004	2.45E-004	1.96E-004	± 5.1 %
DCP (mV) ^B		94.0	94.6	94.5	

Modulation Calibration Parameters

UID	Communication System Name	PAR		A dB	B dB	C dB	VR mV	Unc ^E (k=2)
10000	CW	0.00	X	0.00	0.00	1.00	92.5	±2.7 %
			Y	0.00	0.00	1.00	107.4	
			Z	0.00	0.00	1.00	119.1	

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

⁸ Numerical linearization parameter: uncertainty not required. ^E Uncertainty is determined using the max, deviation from linear response applying rectangular distribution and is expressed for the square of the field value.

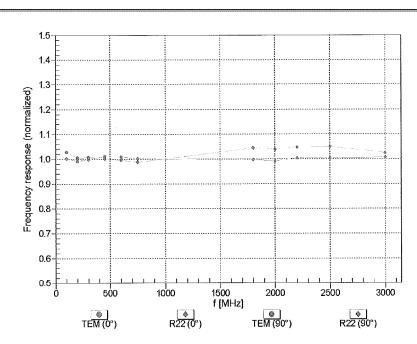
Certificate No: H3-6207_Jan12

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H3DV6-- SN:6207

January 20, 2012



Frequency Response of H-Field (TEM-Cell:ifi110 EXX, Waveguide: R22)

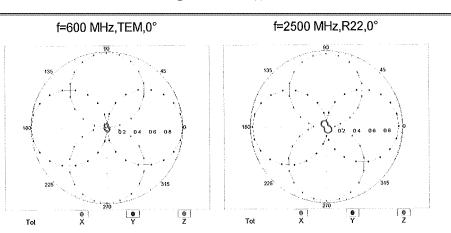
Uncertainty of Frequency Response of H-field: ± 6.3% (k=2)

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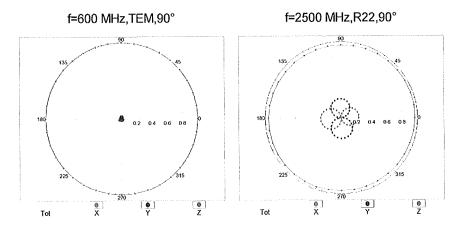
FCC ID: A3LSGHT889	PCTEST	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
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January 20, 2012



Receiving Pattern (ϕ), $\vartheta = 0^{\circ}$

Receiving Pattern (ϕ), ϑ = 90°



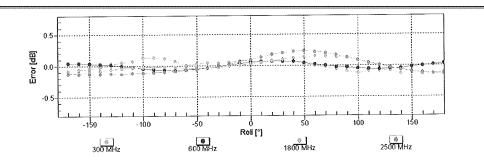
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H3DV6- SN:6207

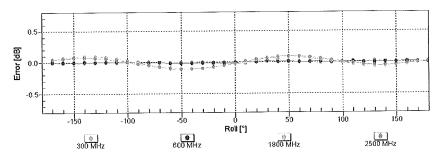
January 20, 2012

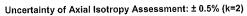




Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

Receiving Pattern (ϕ), ϑ = 90°





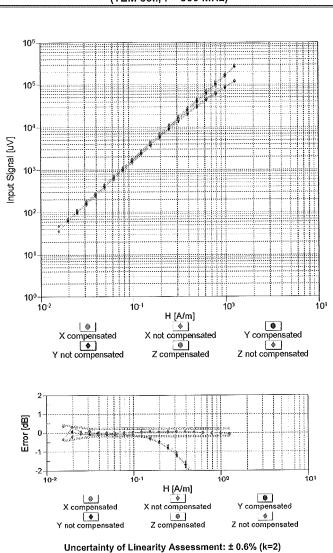
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Dynamic Range f(H-field) (TEM cell, f = 900 MHz)

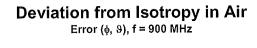
Certificate No: H3-6207_Jan12

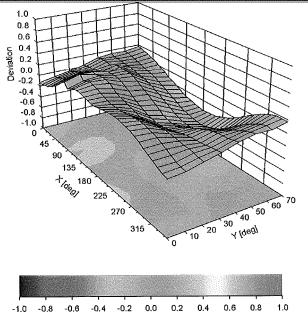
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H3DV6- SN:6207

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Uncertainty of Spherical Isotropy Assessment: ± 2.6% (k=2)

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DASY/EASY - Parameters of Probe: H3DV6 - SN:6207

Other Probe Parameters	
Sensor Arrangement	Rectangular
Connector Angle (°)	179.8
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	337 mm
Probe Body Diameter	10 mm
Tip Length	20 mm
Tip Diameter	6 mm
Probe Tip to Sensor X Calibration Point	3 mm
Probe Tip to Sensor Y Calibration Point	3 mm
Probe Tip to Sensor Z Calibration Point	3 mm

Certificate No: H3-6207_Jan12

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			: CD835V3-1003_Feb11
CALIBRATION	CERTIFICAT	E	
Object	CD835V3 - SN:	1003	
Calibration procedure(s)	QA CAL-20.v5 Calibration proc	edure for dipoles in air	
Calibration date:	February 08, 20	11	Kolczelli
		tional standards, which realize the physical ur ory facility: environment temperature (22 \pm 3)°	
Calibration Equipment used (Ma	&TE critical for calibration)		
Primary Standards	1D #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter EPM-442A	GB37480704	06-Oct-10 (No. 217-01266)	Oct-11
Power sensor HP 8481A	US37292783	06-Oct-10 (No. 217-01266)	Oct-11
Probe ER3DV6	SN: 2336	29-Dec-10 (No. ER3-2336_Dec10)	Dec-11
Probe H3DV6	SN: 6065	29-Dec-10 (No. H3-6065_Dec10)	Dec-11
DAE4	SN: 781	20-Oct-10 (No. DAE4-781_Oct10)	Oct-11
Secondary Standards	ID #	Check Date (in house)	Scheduled Check
Power meter Agilent 4419B	SN: GB42420191	09-Oct-09 (in house check Oct-10)	In house check: Oct-11
Power sensor HP 8482H	SN: 3318A09450	09-Oct-09 (in house check Oct-10)	In house check: Oct-11
Power sensor HP 8482A	SN: US37295597	09-Oct-09 (in house check Oct-10)	In house check: Oct-11
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-10)	In house check: Oct-11
RF generator E4433B	MY 41000675	03-Nov-04 (in house check Oct-09)	In house check: Oct-11
	Name	Function	Signature
Calibrated by:	Claudio Leubler	Laboratory Technician	
Approved by:	Kalja Pokovic	Technical Manager	Jol ky
			Issued: February 10, 2011
This calibration certificate shall	not be reproduced except	n full without written approval of the laborator	<i>y</i>

 FCC ID: A3LSGHT889
 CRF EMISSIONS) TEST REPORT
 Reviewed by: Quality Manager

 Filename: 0Y1208241215.A3L
 Test Dates: 9/6/2012
 EUT Type: Portable Handset
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References

[2]

[1] ANSI-C63.19-2006

American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Alds.

ANSI-C63.19-2007 American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes. In coincidence with the standards [1, 2], the measurement planes (probe sensor center) are selected to be at a distance of 10 mm above the top edge of the dipole arms.
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate. All figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horlzontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the accuracy.
- Feed Point Impedance and Return Loss: These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- E- field distribution: E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1, 2], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 10 mm (in z) above the top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, 10mm above the dipole surface.
- H-field distribution: H-field is measured with an isotropic H-field probe with 100mW forward power to the
 antenna feed point, in the x-y-plane. The scan area and sensor distance is equivalent to the E-field
 scan. The maximum of the field is available at the center (subgrid 5) above the feed point. The H-field
 value stated as calibration value represents the maximum of the interpolated H-field, 10mm above the
 dipole surface at the feed point.

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1 Measurement Conditions

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.6.1 (408)
DASY PP Version	SEMCAD X	V14.4.2 (2595)
Phantom	HAC Test Arch	SD HAC P01 BA, #1070
Distance Dipole Top - Probe Center	10 mm	
Scan resolution	dx, dy = 5 mm	area = 20 x 180 mm
Frequency	835 MHz ± 1 MHz	
Forward power at dipole connector	20.0 dBm = 100mW	
Input power drift	< 0.05 dB	

2 Maximum Field values

H-field 10 mm above dipole surface	condition	interpolated maximum
Maximum measured	100 mW forward power	0.458 A/m
Uncertainty for H-field measurement: 8.2% (k=2)		

E-field 10 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end-	100 mW forward power	170.7 V/m
Maximum measured above low end	100 mW forward power	161.3 V/m
Averaged maximum above arm	100 mW forward power	166.0 V/m

Uncertainty for E-field measurement: 12.8% (k=2)

3 Appendix

3.1 Antenna Parameters

Frequency	Return Loss	Impedance
800 MHz	16.6 dB	(41.9 – 11.1) Ohm
835 MHz	24.1 dB	(48.2 + j5.9) Ohm
900 MHz	16.5 dB	(58.5 – 14.0) Ohm
950 MHz	17.9 dB	(49.3 + j12.8) Ohm
960 MHz	12.9 dB	(62.2 + j22.8) Ohm

3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

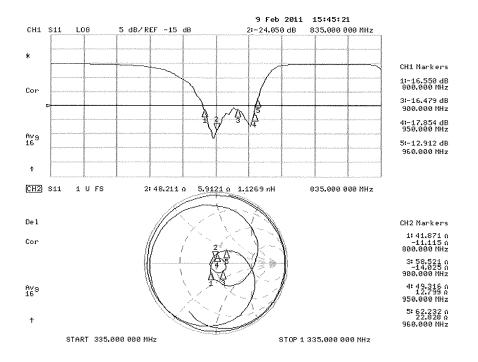
After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

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3.3 Measurement Sheets



3.3.1 Return Loss and Smith Chart

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3.3.3 DASY4 H-field Result

Date/Time: 08.02.2011 13:00:11

Test Laboratory: SPEAG Lab2

HAC RF_CD835_1003_H_110208_CL

DUT: HAC-Dipole 835 MHz; Type: CD835V3; Serial: 1003

Communication System: CW; Frequency: 835 MHz Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³ Phantom section: RF Section Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 SN6065; ; Calibrated: 29.12.2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.10.2010
 Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY52, V52.6.1 Build (408)
- Postprocessing SW: SEMCAD X, V14.4.2 Build (2595)

Dipole H-Field measurement @ 835MHz/H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.458 A/m

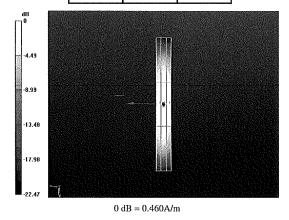
Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.488 A/m; Power Drift = -0.0088 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.376	0.398	0.379
M4	M4	M4
Grid 4	Grid 5	Grid 6
0.435	0.458	0.434
M4	M4	M4
Grid 7	Grid 8	Grid 9
0.388	0.407	0.381
M4	M4	M4



Certificate No: CD835V3-1003_Feb11

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3.3.2 DASY4 E-field Result

Date/Time: 08.02.2011 13:58:56

Test Laboratory: SPEAG Lab2

HAC RF_CD835_1003_E_110208_CL

DUT: HAC-Dipole 835 MHz; Type: CD835V3; Serial: 1003

Communication System: CW; Frequency: 835 MHz Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³ Phantom section: RF Section Measurement Standard: DASY5 (IEEE/IEC/ANSI C63,19-2007)

DASY5 Configuration:

- Probe: ER3DV6 SN2336; ConvF(1, 1, 1); Calibrated: 29.12.2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.10.2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY52, V52.6.1 Build (408)
- Postprocessing SW: SEMCAD X, V14.4.2 Build (2595)

Dipole E-Field measurement @ 835MHz/E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 170.7 V/m

Probe Modulation Factor = 1.000

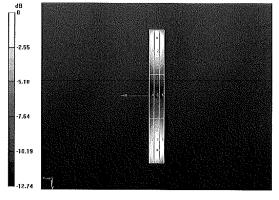
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 123.4 V/m; Power Drift = 0.02 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
164.3	170.7	164.5
M4	M4	M4
Grid 4	Grid 5	Grid 6
85.8	90.5	88.8
M4	M4	M4
Grid 7	Grid 8	Grid 9
152.9	161.3	158.3
M4	M4	M4



 $0 \, dB = 170.7 \, V/m$

Certificate No: CD835V3-1003_Feb11

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Certificate No: CD1880V3-1137_Feb11/2

Dbject	CD1880V3 - SN	: 1137	
Calibration procedure(s)	QA CAL-20.v5 Calibration proc	edure for dipoles in air	
Calibration date:	February 09, 20	11	140t MIN
		tional standards, which realize the physical un ory facility: environment temperature (22 ± 3)°	
Calibration Equipment used (M8	TE critical for calibration)		
Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter EPM-442A	GB37480704	06-Oct-10 (No. 217-01266)	Oct-11
Power sensor HP 8481A	US37292783	06-Oct-10 (No. 217-01266)	Oct-11
Probe ER3DV6	SN: 2336	29-Dec-10 (No. ER3-2336_Dec10)	Dec-11
Probe H3DV6	SN: 6065	29-Dec-10 (No. H3-6065_Dec10)	Dec-11
DAE4	SN: 781	20-Oct-10 (No. DAE4-781_Oct10)	Oct-11
Secondary Standards	1D #	Check Date (in house)	Scheduled Check
Power meter Agilent 4419B	SN: GB42420191	09-Oct-09 (in house check Oct-10)	In house check: Oct-11
Power sensor HP 8482H	SN: 3318A09450	09-Oct-09 (in house check Oct-10)	In house check: Oct-11
Power sensor HP 8482A	SN: US37295597	09-Oct-09 (in house check Oct-10)	In house check: Oct-11
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-10)	In house check: Oct-11
RF generator E4433B	MY 41000675	03-Nov-04 (in house check Oct-09)	In house check: Oct-11
	Name	Function	Signature 1
		Laboratory Technician	lith
Calibrated by:	Claudio Leubler		
Calibrated by: Approved by:	Ciaudio Leubler Katja Pokovio	Technical Manager	Alls

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Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland



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Swiss Calibration Service

С

S

Accreditation No.: SCS 108

Accredited by the Swiss Accreditation Service (SAS) The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

References

[1] ANSI-C63.19-2007

American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes. In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a distance of 10 mm above the top edge of the dipole arms.
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate. All figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the accuracy.
- Feed Point Impedance and Return Loss: These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- E- field distribution: E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 10 mm (in z) above the top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, 10mm above the dipole surface.
- H-field distribution: H-field is measured with an isotropic H-field probe with 100mW forward power to the
 antenna feed point, in the x-y-plane. The scan area and sensor distance is equivalent to the E-field
 scan. The maximum of the field is available at the center (subgrid 5) above the feed point. The H-field
 value stated as calibration value represents the maximum of the interpolated H-field, 10mm above the
 dipole surface at the feed point.

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1. Measurement Conditions

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.6.1 (408)
DASY PP Version	SEMCAD X	V14.4.2 (2595)
Phantom	HAC Test Arch	SD HAC P01 BA, #1070
Distance Dipole Top - Probe Center	10 mm	
Scan resolution	dx, dy = 5 mm	area = 20 x 90 mm
Frequency	1880 MHz ± 1 MHz	
Forward power at dipole connector	20.0 dBm = 100mW	
Input power drift	< 0.05 dB	

2. Maximum Field values

H-field 10 mm above dipole surface	condition	Interpolated maximum
Maximum measured	100 mW forward power	0.460 A/m
Uncertainty for H-field measurement: 8.2% (k=2)		

E-field 10 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW forward power	139.0 V/m
Maximum measured above low end	100 mW forward power	134.5 V/m
Averaged maximum above arm	100 mW forward power	136.8 V/m

Uncertainty for E-field measurement: 12.8% (k=2)

3. Appendix

3.1 Antenna Parameters

Frequency	Return Loss	Impedance
1730 MHz	23.0 dB	(49.6 + j7.1) Ohm
1880 MHz	21.2 dB	(51.1 + j8.7) Ohm
1900 MHz	21.8 dB	(53.3 + 7.7) Ohm
1950 MHz	28.1 dB	(54.1 – j0.2) Ohm
2000 MHz	20.5 dB	(41.4 – j0.8) Ohm

3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

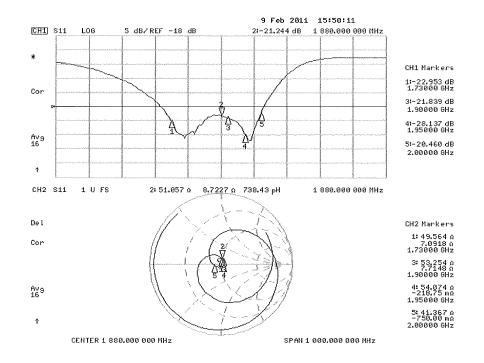
After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

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3.3 Measurement Sheets



3.3.1 Return Loss and Smith Chart

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3.3.2 DASY4 H-Field Result

Date/Time: 09.02.2011 11:34:28

Test Laboratory: SPEAG Lab2

HAC_RF_CD1880_1137_H_110208_CL

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: 1137

Communication System: CW; Frequency: 1880 MHz Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_t = 1$; $\rho = 1$ kg/m³ Phantom section: RF Section Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 SN6065; ; Calibrated: 29.12.2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.10.2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY52, V52.6.1 Build (408)
- Postprocessing SW: SEMCAD X, V14.4.2 Build (2595)

Dipole H-Field measurement @ 1880MHz/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.460 A/m

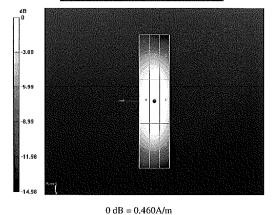
Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.487 A/m; Power Drift = 0.0057 dB Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.401	0.418	0.396
M2	M2	M2
Grid 4	Grid 5	Grid 6
0.443	0.460	0.435
M2	M2	M2
Grid 7	Grid 8	Grid 9
0.409	0.426	0.399
M2	M2	M2



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3.3.3 DASY4 E-Field Result

Date/Time: 08.02.2011 16:54:42

Test Laboratory: SPEAG Lab2

HAC_RF_CD1880_1137_E_110208_CL

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: 1137

Communication System: CW; Frequency: 1880 MHz Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³ Phantom section: RF Section Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 SN2336; ConvF(1, 1, 1); Calibrated: 29.12.2010 •
- Sensor-Surface: (Fix Surface) •
- Electronics: DAE4 Sn781; Calibrated: 20.10.2010 ٠ ٠
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY52, V52.6.1 Build (408) ٠
- Postprocessing SW: SEMCAD X, V14.4.2 Build (2595)

Dipole E-Field measurement @ 1880MHz/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 139.0 V/m

Probe Modulation Factor = 1.000

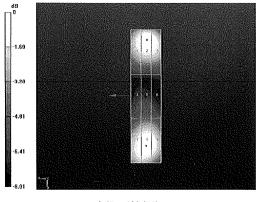
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 138.8 V/m; Power Drift = -0.05 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
131.8	1 39.0	135.0
M2	M2	M2
Grid 4	Grid 5	Grid 6
84.076	87.648	85.767
M3	M3	M3
Grid 7	Grid 8	Grid 9
131.1	134.5	130.5
M2	M2	M2



0 dB = 139.0 V/m

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4. Additional Measurements

4.1 Measurement Conditions

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.6.1 (408)
DASY PP Version	SEMCAD X	V14.4.2 (2595)
Phantom	HAC Test Arch	SD HAC P01 BA, #1070
Distance Dipole Top - Probe Center	10 mm	
Scan resolution	dx, dy = 5 mm	area = 20 x 90 mm
Frequency	1730 MHz ± 1 MHz	
Forward power at dipole connector	20.0 dBm = 100mW	
Input power drift	< 0.05 dB	

4.1.1 Maximum Field values

H-field 10 mm above dipole surface	condition	interpolated maximum
Maximum measured	100 mW forward power	0.489 A/m

Uncertainty for H-field measurement: 8.2% (k=2)

E-field 10 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW forward power	152.7 V/m
Maximum measured above low end	100 mW forward power	150.2 V/m
Averaged maximum above arm	100 mW forward power	151.5 V/m

Uncertainty for E-field measurement: 12.8% (k=2)

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4.1.2 DASY4 H-field result

Date/Time: 09.02.2011 11:27:03

Test Laboratory: SPEAG Lab2

HAC_RF_CD1880_1137_H_1730_110208_CL

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: 1137

Communication System: CW; Frequency: 1730 MHz Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³ Phantom section: RF Section Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

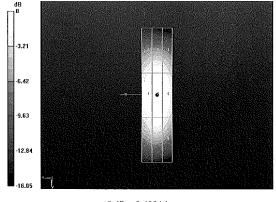
- Probe: H3DV6 SN6065; ; Calibrated: 29.12.2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.10.2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY52, V52.6.1 Build (408)
- Postprocessing SW: SEMCAD X, V14.4.2 Build (2595)

Dipole H-Field measurement @ 1880MHz/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm @ 1730 MHz/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.489 A/m Probe Modulation Factor = 1.000 Device Reference Point: 0, 0, -6.3 mm Reference Value = 0.519 A/m; Power Drift = 0.02 dB Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.407	0.424	0.403
M2	M2	M2
Grid 4	Grid 5	Grid 6
0.467	0.489	0.462
M2	M2	M2
Grid 7	Grid 8	Grid 9
0.418	0.437	0.409
M2	M2	M2



0 dB = 0.490 A/m

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4.1.3 DASY4 E-field result

Date/Time: 08.02.2011 16:26:13

Test Laboratory: SPEAG Lab2

HAC_RF_CD1880_1137_E_1730_110208_CL

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: 1137

Communication System: CW; Frequency: 1730 MHz Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³ Phantom section: RF Section Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 SN2336; ConvF(1, 1, 1); Calibrated: 29.12.2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.10.2010
 Phontom: HAC Test Arch with AMCC: Type: SD HAC P01 BA: Serial:
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY52, V52.6.1 Build (408)
- Postprocessing SW: SEMCAD X, V14.4.2 Build (2595)

Dipole E-Field measurement @ 1880MHz/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm @ 1730 MHz/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 152.7 V/m

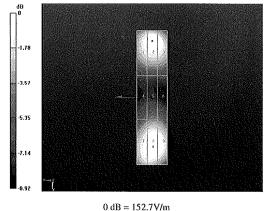
Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 156.8 V/m; Power Drift = 0.0092 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB) Peak E-field in V/n

Grid 1	Grid 2	Grid 3
143.8	150.2	144.8
M2	M2	M2
Grid 4	Grid 5	Grid 6
97.621	103.8	102.2
M3	M3	M3
Grid 7	Grid 8	Grid 9
145.9	152.7	149.2
M2	M2	M2



0 ub = 152.

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15. CONCLUSION

The measurements indicate that the wireless communications device complies with the HAC limits specified in accordance with the ANSI C63.19 Standard and FCC WT Docket No. 01-309 RM-8658. Precise laboratory measures were taken to assure repeatability of the tests. The tested device complies with the requirements in respect to all parameters specific to the test. The test results and statements relate only to the item(s) tested.

Please note that the M-rating for this equipment only represents the field interference possible against a hypothetical and typical hearing aid. The measurement system and techniques presented in this evaluation are proposed in the ANSI standard as a means of best approximating wireless device compatibility with a hearing-aid. The literature is under continual re-construction.

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